



## SUPER-SMALL PACKAGE HIGH-PRECISION VOLTAGE DETECTOR

[www.sii-ic.com](http://www.sii-ic.com)

© Seiko Instruments Inc., 2001-2011

Rev.6.1\_00

The S-808xxC series is a series of high-precision voltage detectors developed using CMOS process. The detection voltage is fixed internally with an accuracy of  $\pm 2.0\%$ . Two output forms, Nch open-drain and CMOS output, are available. Super-low current consumption and miniature package lineup can meet demand from the portable device applications.

### ■ Features

- Super-low current consumption 1.3  $\mu\text{A}$  typ. (detection voltage  $\leq 1.4$  V, at  $V_{DD} = 1.5$  V)  
0.8  $\mu\text{A}$  typ. (detection voltage  $\geq 1.5$  V, at  $V_{DD} = 3.5$  V)
- High-precision detection voltage  $\pm 2.0\%$
- Operating voltage range 0.65 V to 5.0 V (detection voltage  $\leq 1.4$  V)  
0.95 V to 10.0 V (detection voltage  $\geq 1.5$  V)
- Hysteresis characteristics 5% typ.
- Detection voltage 0.8 V to 6.0 V (0.1 V step)
- Output form Nch open-drain output (Active Low)  
CMOS output (Active Low)
- Lead-free, Sn 100%, halogen-free<sup>\*1</sup>

<sup>\*1</sup>1. Refer to "■ Product Name Structure" for details.

### ■ Applications

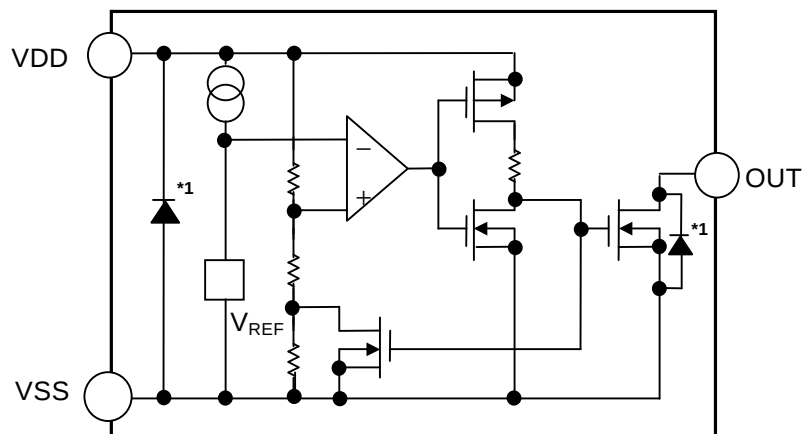
- Battery checkers
- Power failure detectors
- Power monitor for portable equipments such as pagers, calculators, electronic notebooks and remote controllers.
- Constant voltage power monitor for cameras, video equipments and communication devices.
- Power monitor for microcomputers and reset for CPUs.

### ■ Packages

- SC-82AB
- SOT-23-5
- SOT-89-3
- SNT-4A
- TO-92

## ■ Block Diagrams

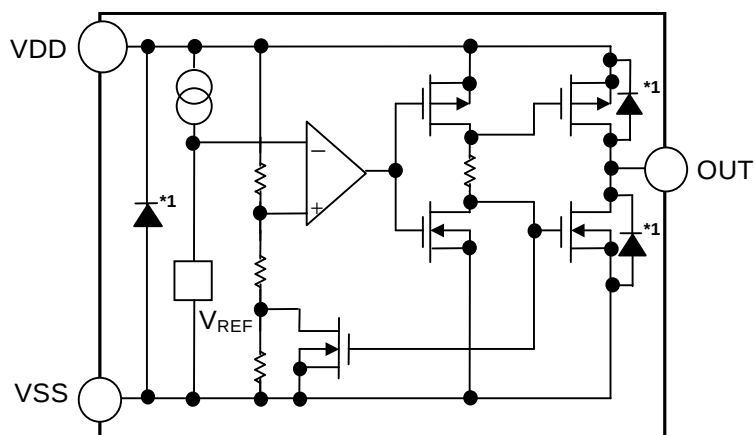
### 1. Nch Open-drain Output Products



\*1. Parasitic diode

Figure 1

### 2. CMOS Output Products



\*1. Parasitic diode

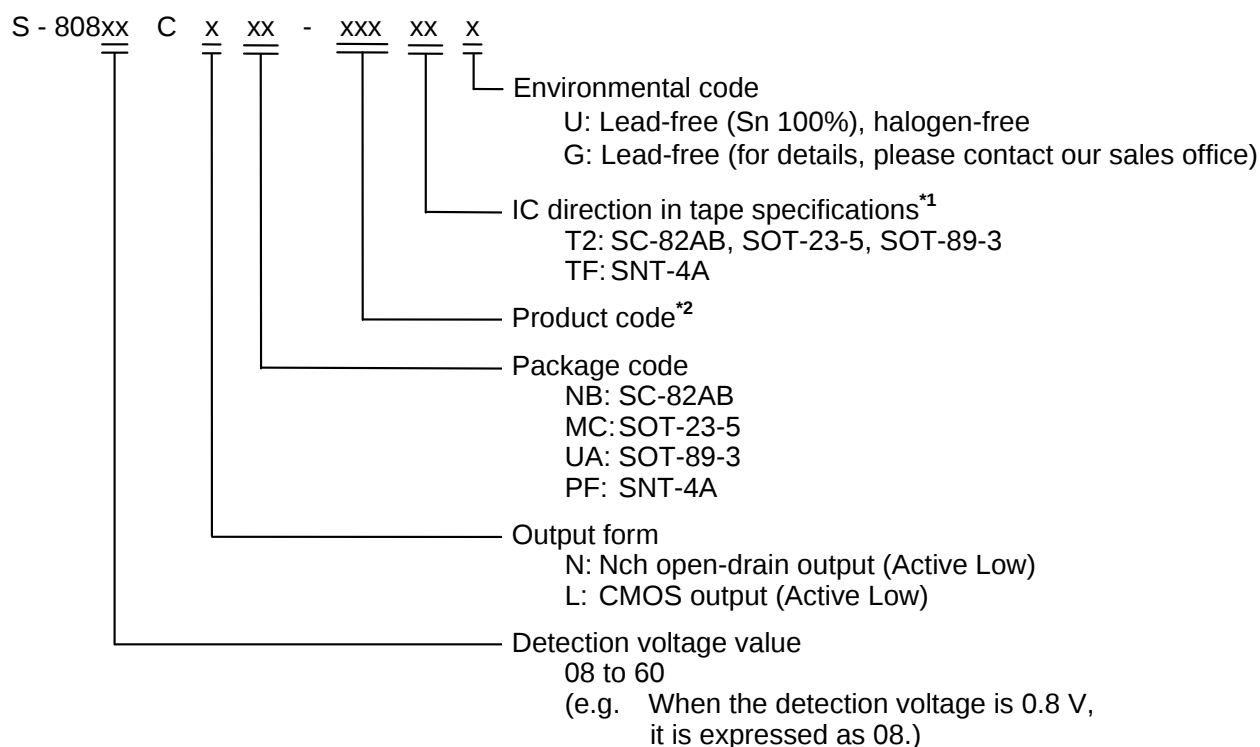
Figure 2

## ■ Product Name Structure

The detection voltage, output form and packages for S-808xxC Series can be selected at the user's request. Refer to the “**1. Product Name**” for the construction of the product name, “**2. Package**” regarding the package drawings and “**3. Product Name List**” for the full product names.

### 1. Product Name

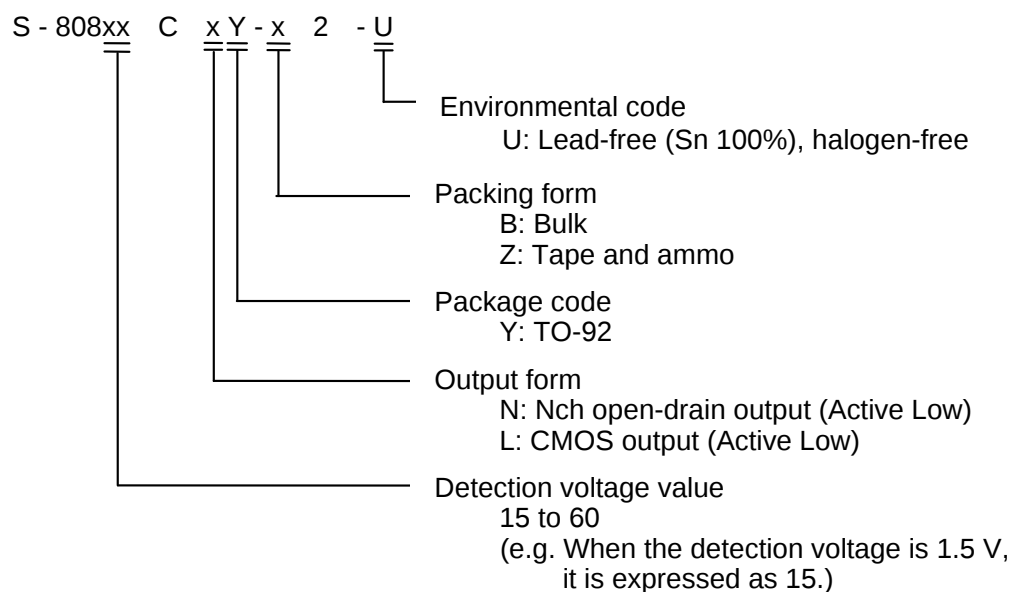
#### 1-1. SC-82AB, SOT-23-5, SOT-89-3, SNT-4A packages



**\*1.** Refer to the tape specifications at the end of this book.

**\*2.** Refer to the **Table 1 and 3** in the “**3. Product Name List**”

## 1-2. TO-92 package



## 2. Packages

| Package name          | Drawing code |                              |              |              |              |
|-----------------------|--------------|------------------------------|--------------|--------------|--------------|
|                       | Package      | Tape                         | Reel         | Zigzag       | Land         |
| SC-82AB               | NP004-A-P-SD | NP004-A-C-SD<br>NP004-A-C-S1 | NP004-A-R-SD | —            | —            |
| SOT-23-5              | MP005-A-P-SD | MP005-A-C-SD                 | MP005-A-R-SD | —            | —            |
| SOT-89-3              | UP003-A-P-SD | UP003-A-C-SD                 | UP003-A-R-SD | —            | —            |
| SNT-4A                | PF004-A-P-SD | PF004-A-C-SD                 | PF004-A-R-SD | —            | PF004-A-L-SD |
| TO-92 (Bulk)          | YS003-D-P-SD | —                            | —            | —            | —            |
| TO-92 (Tape and ammo) | YZ003-E-P-SD | YZ003-E-C-SD                 | —            | YZ003-E-Z-SD | —            |

### 3. Product Name List

#### 3-1. Nch Open-drain Output Products

**Table 1 (1/2)**

| Detection voltage range | Hysteresis width (Typ.)   | SC-82AB            | SOT-23-5           | SOT-89-3                         |
|-------------------------|---------------------------|--------------------|--------------------|----------------------------------|
| 0.8 V±2.0 %             | 0.034 V                   | S-80808CNNB-B9MT2x | —                  | —                                |
| 0.9 V±2.0 %             | 0.044 V                   | S-80809CNNB-B9NT2x | —                  | —                                |
| 1.0 V±2.0 %             | 0.054 V                   | S-80810CNNB-B9OT2x | —                  | —                                |
| 1.1 V±2.0 %             | 0.064 V                   | S-80811CNNB-B9PT2x | —                  | —                                |
| 1.2 V±2.0 %             | 0.073 V                   | S-80812CNNB-B9QT2x | —                  | —                                |
| 1.3 V±2.0 %             | 0.083 V                   | S-80813CNNB-B9RT2x | —                  | —                                |
| 1.4 V±2.0 %             | 0.093 V                   | S-80814CNNB-B9ST2x | —                  | —                                |
| 1.5 V±2.0 %             | 0.075 V                   | S-80815CNNB-B8AT2x | S-80815CNMC-B8AT2x | S-80815CNUA-B8AT2x               |
| 1.6 V±2.0 %             | 0.080 V                   | S-80816CNNB-B8BT2x | S-80816CNMC-B8BT2x | S-80816CNUA-B8BT2x               |
| 1.7 V±2.0 %             | 0.085 V                   | S-80817CNNB-B8CT2x | S-80817CNMC-B8CT2x | S-80817CNUA-B8CT2x               |
| 1.8 V±2.0 %             | 0.090 V                   | S-80818CNNB-B8DT2x | S-80818CNMC-B8DT2x | S-80818CNUA-B8DT2x               |
| 1.9 V±2.0 %             | 0.095 V                   | S-80819CNNB-B8ET2x | S-80819CNMC-B8ET2x | S-80819CNUA-B8ET2x               |
| 2.0 V±2.0 %             | 0.100 V                   | S-80820CNNB-B8FT2x | S-80820CNMC-B8FT2x | S-80820CNUA-B8FT2x               |
| 2.1 V±2.0 %             | 0.105 V                   | S-80821CNNB-B8GT2x | S-80821CNMC-B8GT2x | S-80821CNUA-B8GT2x               |
| 2.2 V±2.0 %             | 0.110 V                   | S-80822CNNB-B8HT2x | S-80822CNMC-B8HT2x | S-80822CNUA-B8HT2x               |
| 2.3 V±2.0 %             | 0.115 V                   | S-80823CNNB-B8IT2x | S-80823CNMC-B8IT2x | S-80823CNUA-B8IT2x               |
| 2.4 V±2.0 %             | 0.120 V                   | S-80824CNNB-B8JT2x | S-80824CNMC-B8JT2x | S-80824CNUA-B8JT2x               |
| 2.4 V typ.              | 4.4 ± 0.1 V <sup>*1</sup> | —                  | —                  | S-80824KNUA-D2BT2x <sup>*2</sup> |
| 2.5 V±2.0 %             | 0.125 V                   | S-80825CNNB-B8KT2x | S-80825CNMC-B8KT2x | S-80825CNUA-B8KT2x               |
| 2.6 V±2.0 %             | 0.130 V                   | S-80826CNNB-B8LT2x | S-80826CNMC-B8LT2x | S-80826CNUA-B8LT2x               |
| 2.7 V±2.0 %             | 0.135 V                   | S-80827CNNB-B8MT2x | S-80827CNMC-B8MT2x | S-80827CNUA-B8MT2x               |
| 2.8 V±2.0 %             | 0.140 V                   | S-80828CNNB-B8NT2x | S-80828CNMC-B8NT2x | S-80828CNUA-B8NT2x               |
| 2.9 V±2.0 %             | 0.145 V                   | S-80829CNNB-B8OT2x | S-80829CNMC-B8OT2x | S-80829CNUA-B8OT2x               |
| 3.0 V±2.0 %             | 0.150 V                   | S-80830CNNB-B8PT2x | S-80830CNMC-B8PT2x | S-80830CNUA-B8PT2x               |
| 3.1 V±2.0 %             | 0.155 V                   | S-80831CNNB-B8QT2x | S-80831CNMC-B8QT2x | S-80831CNUA-B8QT2x               |
| 3.2 V±2.0 %             | 0.160 V                   | S-80832CNNB-B8RT2x | S-80832CNMC-B8RT2x | S-80832CNUA-B8RT2x               |
| 3.3 V±2.0 %             | 0.165 V                   | S-80833CNNB-B8ST2x | S-80833CNMC-B8ST2x | S-80833CNUA-B8ST2x               |
| 3.4 V±2.0 %             | 0.170 V                   | S-80834CNNB-B8TT2x | S-80834CNMC-B8TT2x | S-80834CNUA-B8TT2x               |
| 3.5 V±2.0 %             | 0.175 V                   | S-80835CNNB-B8UT2x | S-80835CNMC-B8UT2x | S-80835CNUA-B8UT2x               |
| 3.6 V±2.0 %             | 0.180 V                   | S-80836CNNB-B8VT2x | S-80836CNMC-B8VT2x | S-80836CNUA-B8VT2x               |
| 3.7 V±2.0 %             | 0.185 V                   | S-80837CNNB-B8WT2x | S-80837CNMC-B8WT2x | S-80837CNUA-B8WT2x               |
| 3.8 V±2.0 %             | 0.190 V                   | S-80838CNNB-B8XT2x | S-80838CNMC-B8XT2x | S-80838CNUA-B8XT2x               |
| 3.9 V±2.0 %             | 0.195 V                   | S-80839CNNB-B8YT2x | S-80839CNMC-B8YT2x | S-80839CNUA-B8YT2x               |

**Table 1 (2/2)**

| Detection voltage range | Hysteresis width (Typ.) | SC-82AB            | SOT-23-5           | SOT-89-3                         |
|-------------------------|-------------------------|--------------------|--------------------|----------------------------------|
| 4.0 V $\pm$ 2.0 %       | 0.200 V                 | S-80840CNNB-B8ZT2x | S-80840CNMC-B8ZT2x | S-80840CNUA-B8ZT2x               |
| 4.1 V $\pm$ 2.0 %       | 0.205 V                 | S-80841CNNB-B82T2x | S-80841CNMC-B82T2x | S-80841CNUA-B82T2x               |
| 4.2 V $\pm$ 2.0 %       | 0.210 V                 | S-80842CNNB-B83T2x | S-80842CNMC-B83T2x | S-80842CNUA-B83T2x               |
| 4.3 V $\pm$ 2.0 %       | 0.215 V                 | S-80843CNNB-B84T2x | S-80843CNMC-B84T2x | S-80843CNUA-B84T2x               |
| 4.4 V $\pm$ 2.0 %       | 0.220 V                 | S-80844CNNB-B85T2x | S-80844CNMC-B85T2x | S-80844CNUA-B85T2x               |
| 4.5 V $\pm$ 2.0 %       | 0.225 V                 | S-80845CNNB-B86T2x | S-80845CNMC-B86T2x | S-80845CNUA-B86T2x               |
| 4.6 V $\pm$ 2.0 %       | 0.230 V                 | S-80846CNNB-B87T2x | S-80846CNMC-B87T2x | S-80846CNUA-B87T2x               |
| 4.6 V $\pm$ 0.10 V      | 0.10 V max.             | —                  | —                  | S-80846KNUA-D2CT2x <sup>*3</sup> |
| 4.7 V $\pm$ 2.0 %       | 0.235 V                 | S-80847CNNB-B88T2x | S-80847CNMC-B88T2x | S-80847CNUA-B88T2x               |
| 4.8 V $\pm$ 2.0 %       | 0.240 V                 | S-80848CNNB-B89T2x | S-80848CNMC-B89T2x | S-80848CNUA-B89T2x               |
| 4.9 V $\pm$ 2.0 %       | 0.245 V                 | S-80849CNNB-B9AT2x | S-80849CNMC-B9AT2x | S-80849CNUA-B9AT2x               |
| 5.0 V $\pm$ 2.0 %       | 0.250 V                 | S-80850CNNB-B9BT2x | S-80850CNMC-B9BT2x | S-80850CNUA-B9BT2x               |
| 5.1 V $\pm$ 2.0 %       | 0.255 V                 | S-80851CNNB-B9CT2x | S-80851CNMC-B9CT2x | S-80851CNUA-B9CT2x               |
| 5.2 V $\pm$ 2.0 %       | 0.260 V                 | S-80852CNNB-B9DT2x | S-80852CNMC-B9DT2x | S-80852CNUA-B9DT2x               |
| 5.3 V $\pm$ 2.0 %       | 0.265 V                 | S-80853CNNB-B9ET2x | S-80853CNMC-B9ET2x | S-80853CNUA-B9ET2x               |
| 5.4 V $\pm$ 2.0 %       | 0.270 V                 | S-80854CNNB-B9FT2x | S-80854CNMC-B9FT2x | S-80854CNUA-B9FT2x               |
| 5.5 V $\pm$ 2.0 %       | 0.275 V                 | S-80855CNNB-B9GT2x | S-80855CNMC-B9GT2x | S-80855CNUA-B9GT2x               |
| 5.6 V $\pm$ 2.0 %       | 0.280 V                 | S-80856CNNB-B9HT2x | S-80856CNMC-B9HT2x | S-80856CNUA-B9HT2x               |
| 5.7 V $\pm$ 2.0 %       | 0.285 V                 | S-80857CNNB-B9IT2x | S-80857CNMC-B9IT2x | S-80857CNUA-B9IT2x               |
| 5.8 V $\pm$ 2.0 %       | 0.290 V                 | S-80858CNNB-B9JT2x | S-80858CNMC-B9JT2x | S-80858CNUA-B9JT2x               |
| 5.9 V $\pm$ 2.0 %       | 0.295 V                 | S-80859CNNB-B9KT2x | S-80859CNMC-B9KT2x | S-80859CNUA-B9KT2x               |
| 6.0 V $\pm$ 2.0 %       | 0.300 V                 | S-80860CNNB-B9LT2x | S-80860CNMC-B9LT2x | S-80860CNUA-B9LT2x               |

\*1. Describes the release voltage.

\*2. Refer to the **Table 18** in “■ Electrical Characteristics for Customized Products” for electrical characteristics.

\*3. Refer to the **Table 20** in “■ Electrical Characteristics for Customized Products” for electrical characteristics

**Remark 1.** x: G or U

2. Please select products of environmental code = U for Sn 100%, halogen-free products.

**Table 2 (1/2)**

| Detection voltage range | Hysteresis width (Typ.)   | SNT-4A             | TO-92 <sup>*1</sup>           |
|-------------------------|---------------------------|--------------------|-------------------------------|
| 0.8 V±2.0 %             | 0.034 V                   | S-80808CNPF-B9MTFx | —                             |
| 0.9 V±2.0 %             | 0.044 V                   | S-80809CNPF-B9NTFx | —                             |
| 1.0 V±2.0 %             | 0.054 V                   | S-80810CNPF-B9OTFx | —                             |
| 1.1 V±2.0 %             | 0.064 V                   | S-80811CNPF-B9PTFx | —                             |
| 1.2 V±2.0 %             | 0.073 V                   | S-80812CNPF-B9QTFx | —                             |
| 1.3 V±2.0 %             | 0.083 V                   | S-80813CNPF-B9RTFx | —                             |
| 1.4 V±2.0 %             | 0.093 V                   | S-80814CNPF-B9STFx | —                             |
| 1.5 V±2.0 %             | 0.075 V                   | S-80815CNPF-B8ATFx | S-80815CNY-n2-U               |
| 1.6 V±2.0 %             | 0.080 V                   | S-80816CNPF-B8BTFx | S-80816CNY-n2-U               |
| 1.7 V±2.0 %             | 0.085 V                   | S-80817CNPF-B8CTFx | S-80817CNY-n2-U               |
| 1.8 V±2.0 %             | 0.090 V                   | S-80818CNPF-B8DTFx | S-80818CNY-n2-U               |
| 1.9 V±2.0 %             | 0.095 V                   | S-80819CNPF-B8ETFx | S-80819CNY-n2-U               |
| 2.0 V±2.0 %             | 0.100 V                   | S-80820CNPF-B8FTFx | S-80820CNY-n2-U               |
| 2.1 V±2.0 %             | 0.105 V                   | S-80821CNPF-B8GTFx | S-80821CNY-n2-U               |
| 2.2 V±2.0 %             | 0.110 V                   | S-80822CNPF-B8HTFx | S-80822CNY-n2-U               |
| 2.3 V±2.0 %             | 0.115 V                   | S-80823CNPF-B8ITFx | S-80823CNY-n2-U               |
| 2.4 V±2.0 %             | 0.120 V                   | S-80824CNPF-B8JTFx | S-80824CNY-n2-U               |
| 2.4 V typ.              | 4.4 ± 0.1 V <sup>*2</sup> | —                  | S-80824KNY-n2-U <sup>*3</sup> |
| 2.5 V±2.0 %             | 0.125 V                   | S-80825CNPF-B8KTFx | S-80825CNY-n2-U               |
| 2.6 V±2.0 %             | 0.130 V                   | S-80826CNPF-B8LTFx | S-80826CNY-n2-U               |
| 2.7 V±2.0 %             | 0.135 V                   | S-80827CNPF-B8MTFx | S-80827CNY-n2-U               |
| 2.8 V±2.0 %             | 0.140 V                   | S-80828CNPF-B8NTFx | S-80828CNY-n2-U               |
| 2.9 V±2.0 %             | 0.145 V                   | S-80829CNPF-B8OTFx | S-80829CNY-n2-U               |
| 3.0 V±2.0 %             | 0.150 V                   | S-80830CNPF-B8PTFx | S-80830CNY-n2-U               |
| 3.1 V±2.0 %             | 0.155 V                   | S-80831CNPF-B8QTFx | S-80831CNY-n2-U               |
| 3.2 V±2.0 %             | 0.160 V                   | S-80832CNPF-B8RTFx | S-80832CNY-n2-U               |
| 3.3 V±2.0 %             | 0.165 V                   | S-80833CNPF-B8STFx | S-80833CNY-n2-U               |
| 3.4 V±2.0 %             | 0.170 V                   | S-80834CNPF-B8TTFx | S-80834CNY-n2-U               |
| 3.5 V±2.0 %             | 0.175 V                   | S-80835CNPF-B8UTFx | S-80835CNY-n2-U               |
| 3.6 V±2.0 %             | 0.180 V                   | S-80836CNPF-B8VTFx | S-80836CNY-n2-U               |
| 3.7 V±2.0 %             | 0.185 V                   | S-80837CNPF-B8WTFx | S-80837CNY-n2-U               |
| 3.8 V±2.0 %             | 0.190 V                   | S-80838CNPF-B8XTFx | S-80838CNY-n2-U               |
| 3.9 V±2.0 %             | 0.195 V                   | S-80839CNPF-B8YTFx | S-80839CNY-n2-U               |
| 4.0 V±2.0 %             | 0.200 V                   | S-80840CNPF-B8ZTFx | S-80840CNY-n2-U               |
| 4.1 V±2.0 %             | 0.205 V                   | S-80841CNPF-B82TFx | S-80841CNY-n2-U               |
| 4.2 V±2.0 %             | 0.210 V                   | S-80842CNPF-B83TFx | S-80842CNY-n2-U               |
| 4.3 V±2.0 %             | 0.215 V                   | S-80843CNPF-B84TFx | S-80843CNY-n2-U               |
| 4.4 V±2.0 %             | 0.220 V                   | S-80844CNPF-B85TFx | S-80844CNY-n2-U               |
| 4.5 V±2.0 %             | 0.225 V                   | S-80845CNPF-B86TFx | S-80845CNY-n2-U               |
| 4.6 V±2.0 %             | 0.230 V                   | S-80846CNPF-B87TFx | S-80846CNY-n2-U               |
| 4.6 V±0.10 V            | 0.10 V max.               | —                  | S-80846KNY-n2-U <sup>*4</sup> |
| 4.7 V±2.0 %             | 0.235 V                   | S-80847CNPF-B88TFx | S-80847CNY-n2-U               |
| 4.8 V±2.0 %             | 0.240 V                   | S-80848CNPF-B89TFx | S-80848CNY-n2-U               |
| 4.9 V±2.0 %             | 0.245 V                   | S-80849CNPF-B9ATFx | S-80849CNY-n2-U               |
| 5.0 V±2.0 %             | 0.250 V                   | S-80850CNPF-B9BTFx | S-80850CNY-n2-U               |
| 5.1 V±2.0 %             | 0.255 V                   | S-80851CNPF-B9CTFx | S-80851CNY-n2-U               |

**Table 2 (2/2)**

| Detection voltage range | Hysteresis width (Typ.) | SNT-4A             | TO-92 <sup>*1</sup> |
|-------------------------|-------------------------|--------------------|---------------------|
| 5.2 V±2.0 %             | 0.260 V                 | S-80852CNPF-B9DTFx | S-80852CNY-n2-U     |
| 5.3 V±2.0 %             | 0.265 V                 | S-80853CNPF-B9ETFx | S-80853CNY-n2-U     |
| 5.4 V±2.0 %             | 0.270 V                 | S-80854CNPF-B9FTFx | S-80854CNY-n2-U     |
| 5.5 V±2.0 %             | 0.275 V                 | S-80855CNPF-B9GTFx | S-80855CNY-n2-U     |
| 5.6 V±2.0 %             | 0.280 V                 | S-80856CNPF-B9HTFx | S-80856CNY-n2-U     |
| 5.7 V±2.0 %             | 0.285 V                 | S-80857CNPF-B9ITFx | S-80857CNY-n2-U     |
| 5.8 V±2.0 %             | 0.290 V                 | S-80858CNPF-B9JTFx | S-80858CNY-n2-U     |
| 5.9 V±2.0 %             | 0.295 V                 | S-80859CNPF-B9KTFx | S-80859CNY-n2-U     |
| 6.0 V±2.0 %             | 0.300 V                 | S-80860CNPF-B9LTFx | S-80860CNY-n2-U     |

**\*1.** n changes according to the packing form in TO-92. B: Bulk, Z: Tape and ammo

**\*2.** Describes the release voltage.

**\*3.** Refer to the **Table 18** in “■ Electrical Characteristics for Customized Products” for electrical characteristics.

**\*4.** Refer to the **Table 20** in “■ Electrical Characteristics for Customized Products” for electrical characteristics.

**Remark 1.** x: G or U

2. Please select products of environmental code = U for Sn 100%, halogen-free products.

**3-2. CMOS Output Products**

**Table 3 (1/2)**

| Detection voltage range | Hysteresis width (Typ.) | SC-82AB            | SOT-23-5           | SOT-89-3             |
|-------------------------|-------------------------|--------------------|--------------------|----------------------|
| 0.8 V±2.0 %             | 0.034 V                 | S-80808CLNB-B7MT2x | —                  | —                    |
| 0.9 V±2.0 %             | 0.044 V                 | S-80809CLNB-B7NT2x | —                  | —                    |
| 1.0 V±2.0 %             | 0.054 V                 | S-80810CLNB-B7OT2x | —                  | —                    |
| 1.1 V±2.0 %             | 0.064 V                 | S-80811CLNB-B7PT2x | —                  | —                    |
| 1.2 V±2.0 %             | 0.073 V                 | S-80812CLNB-B7QT2x | —                  | —                    |
| 1.3 V±2.0 %             | 0.083 V                 | S-80813CLNB-B7RT2x | —                  | —                    |
| 1.4 V±2.0 %             | 0.093 V                 | S-80814CLNB-B7ST2x | —                  | —                    |
| 1.5 V±2.0 %             | 0.075 V                 | S-80815CLNB-B6AT2x | S-80815CLMC-B6AT2x | S-80815CLUA-B6AT2x   |
| 1.6 V±2.0 %             | 0.080 V                 | S-80816CLNB-B6BT2x | S-80816CLMC-B6BT2x | S-80816CLUA-B6BT2x   |
| 1.7 V±2.0 %             | 0.085 V                 | S-80817CLNB-B6CT2x | S-80817CLMC-B6CT2x | S-80817CLUA-B6CT2x   |
| 1.8 V±2.0 %             | 0.090 V                 | S-80818CLNB-B6DT2x | S-80818CLMC-B6DT2x | S-80818CLUA-B6DT2x   |
| 1.9 V±2.0 %             | 0.095 V                 | S-80819CLNB-B6ET2x | S-80819CLMC-B6ET2x | S-80819CLUA-B6ET2x   |
| 2.0 V±2.0 %             | 0.100 V                 | S-80820CLNB-B6FT2x | S-80820CLMC-B6FT2x | S-80820CLUA-B6FT2x   |
| 2.1 V±2.0 %             | 0.105 V                 | S-80821CLNB-B6GT2x | S-80821CLMC-B6GT2x | S-80821CLUA-B6GT2x   |
| 2.2 V±2.0 %             | 0.110 V                 | S-80822CLNB-B6HT2x | S-80822CLMC-B6HT2x | S-80822CLUA-B6HT2x   |
| 2.3 V±2.0 %             | 0.115 V                 | S-80823CLNB-B6IT2x | S-80823CLMC-B6IT2x | S-80823CLUA-B6IT2x   |
| 2.4 V±2.0 %             | 0.120 V                 | S-80824CLNB-B6JT2x | S-80824CLMC-B6JT2x | S-80824CLUA-B6JT2x   |
| 2.5 V±2.0 %             | 0.125 V                 | S-80825CLNB-B6KT2x | S-80825CLMC-B6KT2x | S-80825CLUA-B6KT2x   |
| 2.6 V±2.0 %             | 0.130 V                 | S-80826CLNB-B6LT2x | S-80826CLMC-B6LT2x | S-80826CLUA-B6LT2x   |
| 2.7 V±2.0 %             | 0.135 V                 | S-80827CLNB-B6MT2x | S-80827CLMC-B6MT2x | S-80827CLUA-B6MT2x   |
| 2.8 V±2.0 %             | 0.140 V                 | S-80828CLNB-B6NT2x | S-80828CLMC-B6NT2x | S-80828CLUA-B6NT2x   |
| 2.9 V±2.0 %             | 0.145 V                 | S-80829CLNB-B6OT2x | S-80829CLMC-B6OT2x | S-80829CLUA-B6OT2x   |
| 3.0 V±2.0 %             | 0.150 V                 | S-80830CLNB-B6PT2x | S-80830CLMC-B6PT2x | S-80830CLUA-B6PT2x   |
| 3.1 V±2.0 %             | 0.155 V                 | S-80831CLNB-B6QT2x | S-80831CLMC-B6QT2x | S-80831CLUA-B6QT2x   |
| 3.2 V±2.0 %             | 0.160 V                 | S-80832CLNB-B6RT2x | S-80832CLMC-B6RT2x | S-80832CLUA-B6RT2x   |
| 3.3 V±2.0 %             | 0.165 V                 | S-80833CLNB-B6ST2x | S-80833CLMC-B6ST2x | S-80833CLUA-B6ST2x   |
| 3.4 V±2.0 %             | 0.170 V                 | S-80834CLNB-B6TT2x | S-80834CLMC-B6TT2x | S-80834CLUA-B6TT2x   |
| 3.5 V±2.0 %             | 0.175 V                 | S-80835CLNB-B6UT2x | S-80835CLMC-B6UT2x | S-80835CLUA-B6UT2x   |
| 3.6 V±2.0 %             | 0.180 V                 | S-80836CLNB-B6VT2x | S-80836CLMC-B6VT2x | S-80836CLUA-B6VT2x   |
| 3.7 V±2.0 %             | 0.185 V                 | S-80837CLNB-B6WT2x | S-80837CLMC-B6WT2x | S-80837CLUA-B6WT2x   |
| 3.8 V±2.0 %             | 0.190 V                 | S-80838CLNB-B6XT2x | S-80838CLMC-B6XT2x | S-80838CLUA-B6XT2x   |
| 3.9 V±2.0 %             | 0.195 V                 | S-80839CLNB-B6YT2x | S-80839CLMC-B6YT2x | S-80839CLUA-B6YT2x   |
| 4.0 V±2.0 %             | 0.200 V                 | S-80840CLNB-B6ZT2x | S-80840CLMC-B6ZT2x | S-80840CLUA-B6ZT2x   |
| 4.1 V±2.0 %             | 0.205 V                 | S-80841CLNB-B62T2x | S-80841CLMC-B62T2x | S-80841CLUA-B62T2x   |
| 4.2 V±2.0 %             | 0.210 V                 | S-80842CLNB-B63T2x | S-80842CLMC-B63T2x | S-80842CLUA-B63T2x   |
| 4.3 V±2.0 %             | 0.215 V                 | S-80843CLNB-B64T2x | S-80843CLMC-B64T2x | S-80843CLUA-B64T2x   |
| 4.4 V±2.0 %             | 0.220 V                 | S-80844CLNB-B65T2x | S-80844CLMC-B65T2x | S-80844CLUA-B65T2x   |
| 4.45 V typ.             | 4.70 V max.*1           | —                  | —                  | S-80844KLUA-D2AT2x*2 |
| 4.5 V±2.0 %             | 0.225 V                 | S-80845CLNB-B66T2x | S-80845CLMC-B66T2x | S-80845CLUA-B66T2x   |
| 4.6 V±2.0 %             | 0.230 V                 | S-80846CLNB-B67T2x | S-80846CLMC-B67T2x | S-80846CLUA-B67T2x   |
| 4.7 V±2.0 %             | 0.235 V                 | S-80847CLNB-B68T2x | S-80847CLMC-B68T2x | S-80847CLUA-B68T2x   |
| 4.8 V±2.0 %             | 0.240 V                 | S-80848CLNB-B69T2x | S-80848CLMC-B69T2x | S-80848CLUA-B69T2x   |
| 4.9 V±2.0 %             | 0.245 V                 | S-80849CLNB-B7AT2x | S-80849CLMC-B7AT2x | S-80849CLUA-B7AT2x   |
| 5.0 V±2.0 %             | 0.250 V                 | S-80850CLNB-B7BT2x | S-80850CLMC-B7BT2x | S-80850CLUA-B7BT2x   |
| 5.1 V±2.0 %             | 0.255 V                 | S-80851CLNB-B7CT2x | S-80851CLMC-B7CT2x | S-80851CLUA-B7CT2x   |

**Table 3 (2/2)**

| Detection voltage range | Hysteresis width (Typ.) | SC-82AB            | SOT-23-5           | SOT-89-3           |
|-------------------------|-------------------------|--------------------|--------------------|--------------------|
| 5.2 V±2.0 %             | 0.260 V                 | S-80852CLNB-B7DT2x | S-80852CLMC-B7DT2x | S-80852CLUA-B7DT2x |
| 5.3 V±2.0 %             | 0.265 V                 | S-80853CLNB-B7ET2x | S-80853CLMC-B7ET2x | S-80853CLUA-B7ET2x |
| 5.4 V±2.0 %             | 0.270 V                 | S-80854CLNB-B7FT2x | S-80854CLMC-B7FT2x | S-80854CLUA-B7FT2x |
| 5.5 V±2.0 %             | 0.275 V                 | S-80855CLNB-B7GT2x | S-80855CLMC-B7GT2x | S-80855CLUA-B7GT2x |
| 5.6 V±2.0 %             | 0.280 V                 | S-80856CLNB-B7HT2x | S-80856CLMC-B7HT2x | S-80856CLUA-B7HT2x |
| 5.7 V±2.0 %             | 0.285 V                 | S-80857CLNB-B7IT2x | S-80857CLMC-B7IT2x | S-80857CLUA-B7IT2x |
| 5.8 V±2.0 %             | 0.290 V                 | S-80858CLNB-B7JT2x | S-80858CLMC-B7JT2x | S-80858CLUA-B7JT2x |
| 5.9 V±2.0 %             | 0.295 V                 | S-80859CLNB-B7KT2x | S-80859CLMC-B7KT2x | S-80859CLUA-B7KT2x |
| 6.0 V±2.0 %             | 0.300 V                 | S-80860CLNB-B7LT2x | S-80860CLMC-B7LT2x | S-80860CLUA-B7LT2x |

\*1. Describes the release voltage.

\*2. Refer to the **Table 19** in “■ Electrical Characteristics for Customized Products” for electrical characteristics.

**Remark 1.** x: G or U

2. Please select products of environmental code = U for Sn 100%, halogen-free products.

**Table 4 (1/2)**

| Detection voltage range | Hysteresis width (Typ.) | SNT-4A             | TO-92 <sup>*1</sup> |
|-------------------------|-------------------------|--------------------|---------------------|
| 0.8 V±2.0 %             | 0.034 V                 | S-80808CLPF-B7MTFx | —                   |
| 0.9 V±2.0 %             | 0.044 V                 | S-80809CLPF-B7NTFx | —                   |
| 1.0 V±2.0 %             | 0.054 V                 | S-80810CLPF-B7OTFx | —                   |
| 1.1 V±2.0 %             | 0.064 V                 | S-80811CLPF-B7PTFx | —                   |
| 1.2 V±2.0 %             | 0.073 V                 | S-80812CLPF-B7QTFx | —                   |
| 1.3 V±2.0 %             | 0.083 V                 | S-80813CLPF-B7RTFx | —                   |
| 1.4 V±2.0 %             | 0.093 V                 | S-80814CLPF-B7STFx | —                   |
| 1.5 V±2.0 %             | 0.075 V                 | S-80815CLPF-B6ATFx | S-80815CLY-n2-U     |
| 1.6 V±2.0 %             | 0.080 V                 | S-80816CLPF-B6BTFx | S-80816CLY-n2-U     |
| 1.7 V±2.0 %             | 0.085 V                 | S-80817CLPF-B6CTFx | S-80817CLY-n2-U     |
| 1.8 V±2.0 %             | 0.090 V                 | S-80818CLPF-B6DTFx | S-80818CLY-n2-U     |
| 1.9 V±2.0 %             | 0.095 V                 | S-80819CLPF-B6ETFx | S-80819CLY-n2-U     |
| 2.0 V±2.0 %             | 0.100 V                 | S-80820CLPF-B6FTFx | S-80820CLY-n2-U     |
| 2.1 V±2.0 %             | 0.105 V                 | S-80821CLPF-B6GTFx | S-80821CLY-n2-U     |
| 2.2 V±2.0 %             | 0.110 V                 | S-80822CLPF-B6HTFx | S-80822CLY-n2-U     |
| 2.3 V±2.0 %             | 0.115 V                 | S-80823CLPF-B6ITFx | S-80823CLY-n2-U     |
| 2.4 V±2.0 %             | 0.120 V                 | S-80824CLPF-B6JTFx | S-80824CLY-n2-U     |
| 2.5 V±2.0 %             | 0.125 V                 | S-80825CLPF-B6KTFx | S-80825CLY-n2-U     |
| 2.6 V±2.0 %             | 0.130 V                 | S-80826CLPF-B6LTFx | S-80826CLY-n2-U     |
| 2.7 V±2.0 %             | 0.135 V                 | S-80827CLPF-B6MTFx | S-80827CLY-n2-U     |
| 2.8 V±2.0 %             | 0.140 V                 | S-80828CLPF-B6NTFx | S-80828CLY-n2-U     |
| 2.9 V±2.0 %             | 0.145 V                 | S-80829CLPF-B6OTFx | S-80829CLY-n2-U     |
| 3.0 V±2.0 %             | 0.150 V                 | S-80830CLPF-B6PTFx | S-80830CLY-n2-U     |
| 3.1 V±2.0 %             | 0.155 V                 | S-80831CLPF-B6QTFx | S-80831CLY-n2-U     |
| 3.2 V±2.0 %             | 0.160 V                 | S-80832CLPF-B6RTFx | S-80832CLY-n2-U     |
| 3.3 V±2.0 %             | 0.165 V                 | S-80833CLPF-B6STFx | S-80833CLY-n2-U     |
| 3.4 V±2.0 %             | 0.170 V                 | S-80834CLPF-B6TTFx | S-80834CLY-n2-U     |
| 3.5 V±2.0 %             | 0.175 V                 | S-80835CLPF-B6UTFx | S-80835CLY-n2-U     |
| 3.6 V±2.0 %             | 0.180 V                 | S-80836CLPF-B6VTFx | S-80836CLY-n2-U     |
| 3.7 V±2.0 %             | 0.185 V                 | S-80837CLPF-B6WTFx | S-80837CLY-n2-U     |
| 3.8 V±2.0 %             | 0.190 V                 | S-80838CLPF-B6XTFx | S-80838CLY-n2-U     |

**Table 4 (2/2)**

| Detection voltage range | Hysteresis width (Typ.)   | SNT-4A             | TO-92 <sup>*1</sup>           |
|-------------------------|---------------------------|--------------------|-------------------------------|
| 3.9 V±2.0 %             | 0.195 V                   | S-80839CLPF-B6YTFx | S-80839CLY-n2-U               |
| 4.0 V±2.0 %             | 0.200 V                   | S-80840CLPF-B6ZTFx | S-80840CLY-n2-U               |
| 4.1 V±2.0 %             | 0.205 V                   | S-80841CLPF-B62TFx | S-80841CLY-n2-U               |
| 4.2 V±2.0 %             | 0.210 V                   | S-80842CLPF-B63TFx | S-80842CLY-n2-U               |
| 4.3 V±2.0 %             | 0.215 V                   | S-80843CLPF-B64TFx | S-80843CLY-n2-U               |
| 4.4 V±2.0 %             | 0.220 V                   | S-80844CLPF-B65TFx | S-80844CLY-n2-U               |
| 4.45 V typ.             | 4.70 V max. <sup>*2</sup> | —                  | S-80844KLY-n2-U <sup>*3</sup> |
| 4.5 V±2.0 %             | 0.225 V                   | S-80845CLPF-B66TFx | S-80845CLY-n2-U               |
| 4.6 V±2.0 %             | 0.230 V                   | S-80846CLPF-B67TFx | S-80846CLY-n2-U               |
| 4.7 V±2.0 %             | 0.235 V                   | S-80847CLPF-B68TFx | S-80847CLY-n2-U               |
| 4.8 V±2.0 %             | 0.240 V                   | S-80848CLPF-B69TFx | S-80848CLY-n2-U               |
| 4.9 V±2.0 %             | 0.245 V                   | S-80849CLPF-B7ATFx | S-80849CLY-n2-U               |
| 5.0 V±2.0 %             | 0.250 V                   | S-80850CLPF-B7BTFx | S-80850CLY-n2-U               |
| 5.1 V±2.0 %             | 0.255 V                   | S-80851CLPF-B7CTFx | S-80851CLY-n2-U               |
| 5.2 V±2.0 %             | 0.260 V                   | S-80852CLPF-B7DTFx | S-80852CLY-n2-U               |
| 5.3 V±2.0 %             | 0.265 V                   | S-80853CLPF-B7ETFx | S-80853CLY-n2-U               |
| 5.4 V±2.0 %             | 0.270 V                   | S-80854CLPF-B7FTFx | S-80854CLY-n2-U               |
| 5.5 V±2.0 %             | 0.275 V                   | S-80855CLPF-B7GTFx | S-80855CLY-n2-U               |
| 5.6 V±2.0 %             | 0.280 V                   | S-80856CLPF-B7HTFx | S-80856CLY-n2-U               |
| 5.7 V±2.0 %             | 0.285 V                   | S-80857CLPF-B7ITFx | S-80857CLY-n2-U               |
| 5.8 V±2.0 %             | 0.290 V                   | S-80858CLPF-B7JTFx | S-80858CLY-n2-U               |
| 5.9 V±2.0 %             | 0.295 V                   | S-80859CLPF-B7KTFx | S-80859CLY-n2-U               |
| 6.0 V±2.0 %             | 0.300 V                   | S-80860CLPF-B7LTFx | S-80860CLY-n2-U               |

**\*1.** n changes according to the packing form in TO-92. B: Bulk, Z: Tape and ammo

**\*2.** Describes the release voltage.

**\*3.** Refer to the **Table 19** in “■ Electrical Characteristics for Customized Products” for electrical characteristics.

**Remark 1.** x: G or U

2. Please select products of environmental code = U for Sn 100%, halogen-free products.

## ■ Output Forms

### 1. Output Forms in S-808xxC Series

**Table 5**

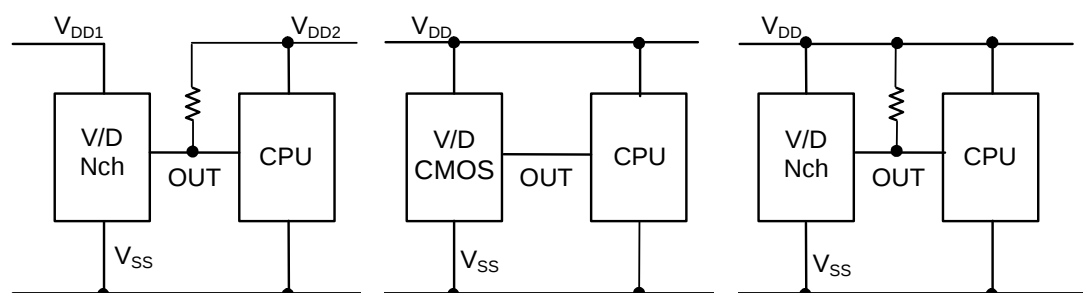
|                 | Nch open-drain output products<br>(Active Low)                | CMOS output products<br>(Active Low)                          |
|-----------------|---------------------------------------------------------------|---------------------------------------------------------------|
| S-808xxC Series | "N" is the last letter of the product name.<br>e.g. S-80815CN | "L" is the last letter of the product name.<br>e.g. S-80815CL |

### 2. Output Forms and Their Usage

**Table 6**

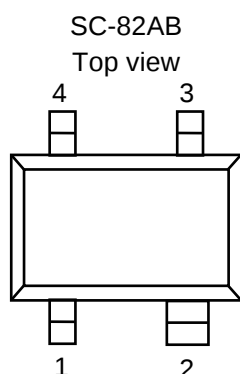
| Usage                                        | Nch open-drain output products<br>(Active Low) | CMOS output products<br>(Active Low) |
|----------------------------------------------|------------------------------------------------|--------------------------------------|
| Different power supplies                     | Yes                                            | No                                   |
| Active Low reset for CPUs                    | Yes                                            | Yes                                  |
| Active High reset for CPUs                   | No                                             | No                                   |
| Detection voltage change by resistor divider | Yes                                            | No                                   |

- Example for two power supplies
- Example for one power supply

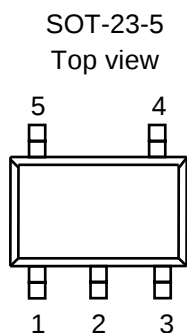


**Figure 3**

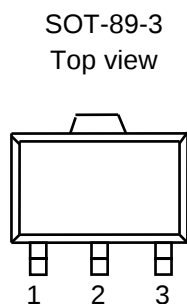
■ **Pin Configurations**



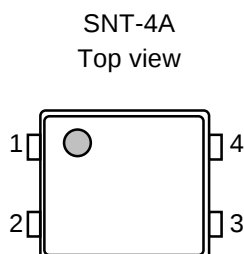
**Figure 4**



**Figure 5**



**Figure 6**



**Figure 7**

**Table 7**

| Pin No. | Symbol           | Description                  |
|---------|------------------|------------------------------|
| 1       | OUT              | Voltage detection output pin |
| 2       | VDD              | Voltage input pin            |
| 3       | NC <sup>*1</sup> | No connection                |
| 4       | VSS              | GND pin                      |

<sup>\*1</sup>. The NC pin is electrically open.  
The NC pin can be connected to VDD or VSS.

**Table 8**

| Pin No. | Symbol           | Description                  |
|---------|------------------|------------------------------|
| 1       | OUT              | Voltage detection output pin |
| 2       | VDD              | Voltage input pin            |
| 3       | VSS              | GND pin                      |
| 4       | NC <sup>*1</sup> | No connection                |
| 5       | NC <sup>*1</sup> | No connection                |

<sup>\*1</sup>. The NC pin is electrically open.  
The NC pin can be connected to VDD or VSS.

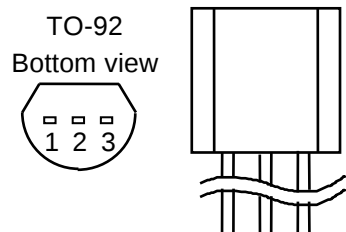
**Table 9**

| Pin No. | Symbol | Description                  |
|---------|--------|------------------------------|
| 1       | OUT    | Voltage detection output pin |
| 2       | VDD    | Voltage input pin            |
| 3       | VSS    | GND pin                      |

**Table10**

| Pin No. | Symbol           | Description                  |
|---------|------------------|------------------------------|
| 1       | OUT              | Voltage detection output pin |
| 2       | VSS              | GND pin                      |
| 3       | NC <sup>*1</sup> | No connection                |
| 4       | VDD              | Voltage input pin            |

<sup>\*1</sup>. The NC pin is electrically open.  
The NC pin can be connected to VDD or VSS.



**Figure 8**

**Table 11**

| Pin No. | Symbol | Description                  |
|---------|--------|------------------------------|
| 1       | OUT    | Voltage detection output pin |
| 2       | VDD    | Voltage input pin            |
| 3       | VSS    | GND pin                      |

■ **Absolute Maximum Ratings**

**1. Detection Voltage Typ. 1.4 V or Less Products**

**Table 12**

(Ta = 25 °C unless otherwise specified)

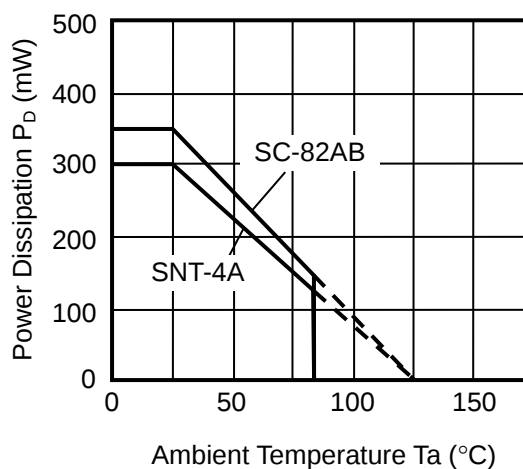
| Item                          |                                | Symbol          | Absolute maximum ratings        | Unit |
|-------------------------------|--------------------------------|-----------------|---------------------------------|------|
| Power supply voltage          |                                | $V_{DD}-V_{SS}$ | 7                               | V    |
| Output voltage                | Nch open-drain output products | $V_{OUT}$       | $V_{SS}-0.3$ to $V_{SS}+7$      | V    |
|                               | CMOS output products           |                 | $V_{SS}-0.3$ to $V_{DD}+0.3$    | V    |
| Output current                |                                | $I_{OUT}$       | 50                              | mA   |
| Power dissipation             | SC-82AB                        | $P_D$           | 150 (When not mounted on board) | mW   |
|                               |                                |                 | 350 <sup>*1</sup>               | mW   |
|                               | SNT-4A                         |                 | 140 (When not mounted on board) | mW   |
|                               |                                |                 | 300 <sup>*1</sup>               | mW   |
| Operating ambient temperature |                                | $T_{opr}$       | -40 to +85                      | °C   |
| Storage temperature           |                                | $T_{stg}$       | -40 to +125                     | °C   |

**\*1.** When mounted on board

[Mounted board]

- (1) Board size: 114.3 mm × 76.2 mm × t1.6 mm
- (2) Board name: JEDEC STANDARD51-7

**Caution** The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



**Figure 9 Power Dissipation of Package (When Mounted on Board)**

**2. Detection Voltage Typ. 1.5 V or More Products**

**Table 13**

(Ta = 25 °C unless otherwise specified)

| Item                          |                                | Symbol          | Absolute maximum ratings        | Unit |
|-------------------------------|--------------------------------|-----------------|---------------------------------|------|
| Power supply voltage          |                                | $V_{DD}-V_{SS}$ | 12                              | V    |
| Output voltage                | Nch open-drain output products | $V_{OUT}$       | $V_{SS}-0.3$ to $V_{SS}+12$     | V    |
|                               | CMOS output products           |                 | $V_{SS}-0.3$ to $V_{DD}+0.3$    | V    |
| Output current                |                                | $I_{OUT}$       | 50                              | mA   |
| Power dissipation             | SC-82AB                        | $P_D$           | 150 (When not mounted on board) | mW   |
|                               |                                |                 | 350 <sup>*1</sup>               | mW   |
|                               | SOT-23-5                       |                 | 250 (When not mounted on board) | mW   |
|                               |                                |                 | 600 <sup>*1</sup>               | mW   |
|                               | SOT-89-3                       |                 | 500 (When not mounted on board) | mW   |
|                               |                                |                 | 1000 <sup>*1</sup>              | mW   |
|                               | SNT-4A                         |                 | 140 (When not mounted on board) | mW   |
|                               |                                |                 | 300 <sup>*1</sup>               | mW   |
|                               | TO-92                          |                 | 400 (When not mounted on board) | mW   |
|                               |                                |                 | 800 <sup>*1</sup>               | mW   |
| Operating ambient temperature |                                | $T_{opr}$       | -40 to +85                      | °C   |
| Storage temperature           |                                | $T_{stg}$       | -40 to +125                     | °C   |

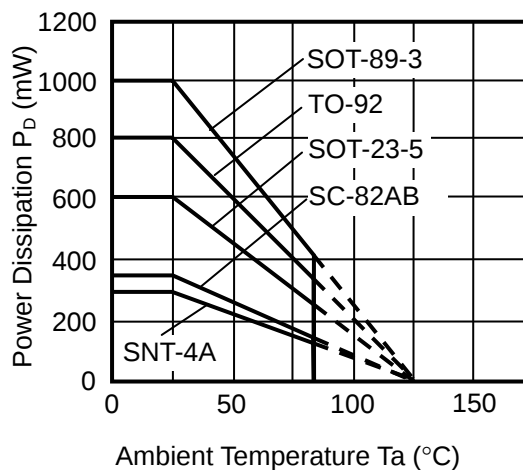
**\*1.** When mounted on board

[Mounted board]

(1) Board size: 114.3 mm × 76.2 mm × t1.6 mm

(2) Board name: JEDEC STANDARD51-7

**Caution** The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.



**Figure 10 Power Dissipation of Package (When Mounted on Board)**

## ■ Electrical Characteristics

### 1. Nch Open-drain Output Products

#### 1-1. Detection Voltage Typ.1.4 V or Less Products

**Table 14**

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                | Condition                                                                      | Min.                      | Typ.          | Max.                      | Unit       | Test circuit |
|---------------------------------------------------------|-------------------------------------------------------|--------------------------------------------------------------------------------|---------------------------|---------------|---------------------------|------------|--------------|
| Detection voltage <sup>*1</sup>                         | $-V_{DET}$                                            | —                                                                              | $-V_{DET(S)} \times 0.98$ | $-V_{DET(S)}$ | $-V_{DET(S)} \times 1.02$ | V          | 1            |
| Release voltage                                         | $+V_{DET}$                                            | S-80808                                                                        | 0.802                     | 0.834         | 0.867                     | V          | 1            |
|                                                         |                                                       | S-80809                                                                        | 0.910                     | 0.944         | 0.979                     | V          | 1            |
|                                                         |                                                       | S-80810                                                                        | 1.017                     | 1.054         | 1.091                     | V          | 1            |
|                                                         |                                                       | S-80811                                                                        | 1.125                     | 1.164         | 1.203                     | V          | 1            |
|                                                         |                                                       | S-80812                                                                        | 1.232                     | 1.273         | 1.315                     | V          | 1            |
|                                                         |                                                       | S-80813                                                                        | 1.340                     | 1.383         | 1.427                     | V          | 1            |
|                                                         |                                                       | S-80814                                                                        | 1.448                     | 1.493         | 1.538                     | V          | 1            |
| Hysteresis width                                        | $V_{HYS}$                                             | S-80808                                                                        | 0.018                     | 0.034         | 0.051                     | V          | 1            |
|                                                         |                                                       | S-80809                                                                        | 0.028                     | 0.044         | 0.061                     | V          | 1            |
|                                                         |                                                       | S-80810                                                                        | 0.037                     | 0.054         | 0.071                     | V          | 1            |
|                                                         |                                                       | S-80811                                                                        | 0.047                     | 0.064         | 0.081                     | V          | 1            |
|                                                         |                                                       | S-80812                                                                        | 0.056                     | 0.073         | 0.091                     | V          | 1            |
|                                                         |                                                       | S-80813                                                                        | 0.066                     | 0.083         | 0.101                     | V          | 1            |
|                                                         |                                                       | S-80814                                                                        | 0.076                     | 0.093         | 0.110                     | V          | 1            |
| Current consumption                                     | $I_{SS}$                                              | $V_{DD} = 1.5 \text{ V}$ S-80808 to 09                                         | —                         | 1.3           | 3.5                       | μA         | 2            |
|                                                         |                                                       | $V_{DD} = 2.0 \text{ V}$ S-80810 to 14                                         | —                         | 1.3           | 3.5                       | μA         | 2            |
| Operating voltage                                       | $V_{DD}$                                              | —                                                                              | 0.65                      | —             | 5.0                       | V          | 1            |
| Output current                                          | $I_{OUT}$                                             | Output transistor,<br>Nch, $V_{DS} = 0.5 \text{ V}$ , $V_{DD} = 0.7 \text{ V}$ | 0.04                      | 0.2           | —                         | mA         | 3            |
| Leakage current                                         | $I_{LEAK}$                                            | Output transistor,<br>Nch, $V_{DS} = 5.0 \text{ V}$ , $V_{DD} = 5.0 \text{ V}$ | —                         | —             | 60                        | nA         | 3            |
| Response time                                           | $t_{PLH}$                                             | —                                                                              | —                         | —             | 60                        | μs         | 1            |
| Detection voltage temperature coefficient <sup>*2</sup> | $\frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}}$ | $Ta = -40 \text{ to } +85 \text{ }^{\circ}\text{C}$                            | —                         | ±100          | ±350                      | ppm/<br>°C | 1            |

**\*1.**  $-V_{DET}$ : Actual detection voltage value,  $-V_{DET(S)}$ : Specified detection voltage value (The center value of the detection voltage range in **Table 1 to 2**.)

**\*2.** The temperature change of the detection voltage [mV/°C] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta Ta} [\text{mV}/^{\circ}\text{C}]^{*1} = -V_{DET(S)} (\text{Typ.}) [\text{V}]^{*2} \times \frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}} [\text{ppm}/^{\circ}\text{C}]^{*3} \div 1000$$

**\*1.** Temperature change of the detection voltage

**\*2.** Specified detection voltage

**\*3.** Detection voltage temperature coefficient

**1-2. Detection Voltage Typ.1.5 V or More Products**

**Table 15**

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                | Condition                                                                                | Min.                      | Typ.                   | Max.                      | Unit   | Test circuit |
|---------------------------------------------------------|-------------------------------------------------------|------------------------------------------------------------------------------------------|---------------------------|------------------------|---------------------------|--------|--------------|
| Detection voltage <sup>*1</sup>                         | $-V_{DET}$                                            | —                                                                                        | $-V_{DET(S)} \times 0.98$ | $-V_{DET(S)}$          | $-V_{DET(S)} \times 1.02$ | V      | 1            |
| Hysteresis width                                        | $V_{HYS}$                                             | —                                                                                        | $-V_{DET} \times 0.03$    | $-V_{DET} \times 0.05$ | $-V_{DET} \times 0.08$    | V      | 1            |
| Current consumption                                     | $I_{SS}$                                              | $V_{DD} = 3.5\text{ V}$ S-80815 to 26                                                    | —                         | 0.8                    | 2.4                       | μA     | 2            |
|                                                         |                                                       | $V_{DD} = 4.5\text{ V}$ S-80827 to 39                                                    | —                         | 0.8                    | 2.4                       | μA     | 2            |
|                                                         |                                                       | $V_{DD} = 6.0\text{ V}$ S-80840 to 56                                                    | —                         | 0.9                    | 2.7                       | μA     | 2            |
|                                                         |                                                       | $V_{DD} = 7.5\text{ V}$ S-80857 to 60                                                    | —                         | 0.9                    | 2.7                       | μA     | 2            |
| Operating voltage                                       | $V_{DD}$                                              | —                                                                                        | 0.95                      | —                      | 10.0                      | V      | 1            |
| Output current                                          | $I_{OUT}$                                             | Output transistor, $V_{DD} = 1.2\text{ V}$<br>Nch, $V_{DS} = 0.5\text{ V}$ S-80815 to 60 | 0.59                      | 1.36                   | —                         | mA     | 3            |
|                                                         |                                                       | $V_{DD} = 2.4\text{ V}$<br>S-80827 to 60                                                 | 2.88                      | 4.98                   | —                         | mA     | 3            |
| Leakage current                                         | $I_{LEAK}$                                            | Output transistor,<br>Nch, $V_{DS} = 10.0\text{ V}$ , $V_{DD} = 10.0\text{ V}$           | —                         | —                      | 100                       | nA     | 3            |
| Response time                                           | $t_{PLH}$                                             | —                                                                                        | —                         | —                      | 60                        | μs     | 1            |
| Detection voltage temperature coefficient <sup>*2</sup> | $\frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}}$ | Ta = -40 to +85 °C                                                                       | —                         | ±100                   | ±350                      | ppm/°C | 1            |

**\*1.**  $-V_{DET}$ : Actual detection voltage value,  $-V_{DET(S)}$ : Specified detection voltage value (The center value of the detection voltage range in **Table 1 to 2.**)

**\*2.** The temperature change of the detection voltage [mV/°C] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta Ta} [\text{mV}/^{\circ}\text{C}]^{*1} = -V_{DET(S)} (\text{Typ.}) [\text{V}]^{*2} \times \frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}} [\text{ppm}/^{\circ}\text{C}]^{*3} \div 1000$$

**\*1.** Temperature change of the detection voltage

**\*2.** Specified detection voltage

**\*3.** Detection voltage temperature coefficient

## 2. CMOS Output Products

### 2-1. Detection Voltage Typ.1.4 V or Less Products

**Table 16**

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                | Condition                                                                   | Min.                      | Typ.          | Max.                      | Unit       | Test circuit |
|---------------------------------------------------------|-------------------------------------------------------|-----------------------------------------------------------------------------|---------------------------|---------------|---------------------------|------------|--------------|
| Detection voltage <sup>*1</sup>                         | $-V_{DET}$                                            | —                                                                           | $-V_{DET(S)} \times 0.98$ | $-V_{DET(S)}$ | $-V_{DET(S)} \times 1.02$ | V          | 1            |
| Release voltage                                         | $+V_{DET}$                                            | S-80808                                                                     | 0.802                     | 0.834         | 0.867                     | V          | 1            |
|                                                         |                                                       | S-80809                                                                     | 0.910                     | 0.944         | 0.979                     | V          | 1            |
|                                                         |                                                       | S-80810                                                                     | 1.017                     | 1.054         | 1.091                     | V          | 1            |
|                                                         |                                                       | S-80811                                                                     | 1.125                     | 1.164         | 1.203                     | V          | 1            |
|                                                         |                                                       | S-80812                                                                     | 1.232                     | 1.273         | 1.315                     | V          | 1            |
|                                                         |                                                       | S-80813                                                                     | 1.340                     | 1.383         | 1.427                     | V          | 1            |
|                                                         |                                                       | S-80814                                                                     | 1.448                     | 1.493         | 1.538                     | V          | 1            |
| Hysteresis width                                        | $V_{HYS}$                                             | S-80808                                                                     | 0.018                     | 0.034         | 0.051                     | V          | 1            |
|                                                         |                                                       | S-80809                                                                     | 0.028                     | 0.044         | 0.061                     | V          | 1            |
|                                                         |                                                       | S-80810                                                                     | 0.037                     | 0.054         | 0.071                     | V          | 1            |
|                                                         |                                                       | S-80811                                                                     | 0.047                     | 0.064         | 0.081                     | V          | 1            |
|                                                         |                                                       | S-80812                                                                     | 0.056                     | 0.073         | 0.091                     | V          | 1            |
|                                                         |                                                       | S-80813                                                                     | 0.066                     | 0.083         | 0.101                     | V          | 1            |
|                                                         |                                                       | S-80814                                                                     | 0.076                     | 0.093         | 0.110                     | V          | 1            |
| Current consumption                                     | $I_{SS}$                                              | $V_{DD} = 1.5 \text{ V}$ S-80808 to 09                                      | —                         | 1.3           | 3.5                       | μA         | 2            |
|                                                         |                                                       | $V_{DD} = 2.0 \text{ V}$ S-80810 to 14                                      | —                         | 1.3           | 3.5                       | μA         | 2            |
| Operating voltage                                       | $V_{DD}$                                              | —                                                                           | 0.65                      | —             | 5.0                       | V          | 1            |
| Output current                                          | $I_{OUT}$                                             | Output transistor, Nch, $V_{DS} = 0.5 \text{ V}$ , $V_{DD} = 0.7 \text{ V}$ | 0.04                      | 0.2           | —                         | mA         | 3            |
|                                                         |                                                       | Output transistor, Pch, $V_{DS} = 2.1 \text{ V}$ , $V_{DD} = 4.5 \text{ V}$ | 2.9                       | 5.8           | —                         | mA         | 4            |
| Response time                                           | $t_{PLH}$                                             | —                                                                           | —                         | —             | 60                        | μs         | 1            |
| Detection voltage temperature coefficient <sup>*2</sup> | $\frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}}$ | $Ta = -40 \text{ to } +85 \text{ }^{\circ}\text{C}$                         | —                         | ±100          | ±350                      | ppm/<br>°C | 1            |

**\*1.**  $-V_{DET}$ : Actual detection voltage value,  $-V_{DET(S)}$ : Specified detection voltage value (The center value of the detection voltage range in **Table 3 to 4**.)

**\*2.** The temperature change of the detection voltage [mV/°C] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta Ta} [\text{mV}/^{\circ}\text{C}]^{*1} = -V_{DET(S)}(\text{Typ.})[\text{V}]^{*2} \times \frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}} [\text{ppm}/^{\circ}\text{C}]^{*3} \div 1000$$

**\*1.** Temperature change of the detection voltage

**\*2.** Specified detection voltage

**\*3.** Detection voltage temperature coefficient

**2-2. Detection Voltage Typ.1.5 V or More Products**

**Table 17**

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                | Condition                                          |                                          | Min.                          | Typ.                       | Max.                          | Unit       | Test circuit |
|---------------------------------------------------------|-------------------------------------------------------|----------------------------------------------------|------------------------------------------|-------------------------------|----------------------------|-------------------------------|------------|--------------|
| Detection voltage <sup>*1</sup>                         | −V <sub>DET</sub>                                     | —                                                  |                                          | −V <sub>DET(S)</sub><br>×0.98 | −V <sub>DET(S)</sub>       | −V <sub>DET(S)</sub><br>×1.02 | V          | 1            |
| Hysteresis width                                        | V <sub>HYS</sub>                                      | —                                                  |                                          | −V <sub>DET</sub><br>×0.03    | −V <sub>DET</sub><br>×0.05 | −V <sub>DET</sub><br>×0.08    | V          | 1            |
| Current consumption                                     | I <sub>SS</sub>                                       | V <sub>DD</sub> = 3.5 V                            | S-80815 to 26                            | —                             | 0.8                        | 2.4                           | μA         | 2            |
|                                                         |                                                       | V <sub>DD</sub> = 4.5 V                            | S-80827 to 39                            | —                             | 0.8                        | 2.4                           | μA         | 2            |
|                                                         |                                                       | V <sub>DD</sub> = 6.0 V                            | S-80840 to 56                            | —                             | 0.9                        | 2.7                           | μA         | 2            |
|                                                         |                                                       | V <sub>DD</sub> = 7.5 V                            | S-80857 to 60                            | —                             | 0.9                        | 2.7                           | μA         | 2            |
| Operating voltage                                       | V <sub>DD</sub>                                       | —                                                  |                                          | 0.95                          | —                          | 10.0                          | V          | 1            |
| Output current                                          | I <sub>OUT</sub>                                      | Output transistor,<br>Nch, V <sub>DS</sub> = 0.5 V | V <sub>DD</sub> = 1.2 V<br>S-80815 to 60 | 0.59                          | 1.36                       | —                             | mA         | 3            |
|                                                         |                                                       |                                                    | V <sub>DD</sub> = 2.4 V<br>S-80827 to 60 | 2.88                          | 4.98                       | —                             | mA         | 3            |
|                                                         |                                                       | Output transistor,<br>Pch, V <sub>DS</sub> = 0.5 V | V <sub>DD</sub> = 4.8 V<br>S-80815 to 39 | 1.43                          | 2.39                       | —                             | mA         | 4            |
|                                                         |                                                       |                                                    | V <sub>DD</sub> = 6.0 V<br>S-80840 to 56 | 1.68                          | 2.78                       | —                             | mA         | 4            |
|                                                         |                                                       |                                                    | V <sub>DD</sub> = 8.4 V<br>S-80857 to 60 | 2.08                          | 3.42                       | —                             | mA         | 4            |
| Response time                                           | t <sub>PLH</sub>                                      | —                                                  |                                          | —                             | —                          | 60                            | μs         | 1            |
| Detection voltage temperature coefficient <sup>*2</sup> | $\frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}}$ | Ta = −40 to +85 °C                                 |                                          | —                             | ±100                       | ±350                          | ppm/<br>°C | 1            |

**\*1.**  $-V_{DET}$ : Actual detection voltage value,  $-V_{DET(S)}$ : Specified detection voltage value (The center value of the detection voltage range in **Table 3 to 4.**)

**\*2.** The temperature change of the detection voltage [mV/°C] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta Ta} [\text{mV}/^\circ\text{C}]^{*1} = -V_{DET(S)} (\text{Typ.}) [\text{V}]^{*2} \times \frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}} [\text{ppm}/^\circ\text{C}]^{*3} \div 1000$$

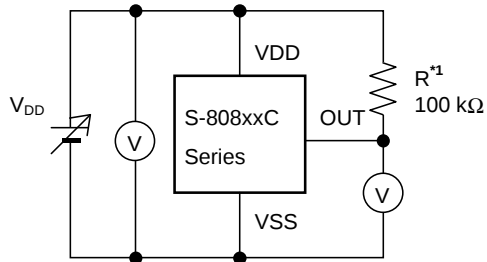
**\*1.** Temperature change of the detection voltage

**\*2.** Specified detection voltage

**\*3.** Detection voltage temperature coefficient

## ■ Test Circuits

1.



\*1. R is unnecessary for CMOS output products.

Figure 11

2.

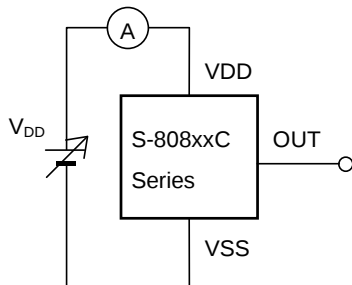


Figure 12

3.

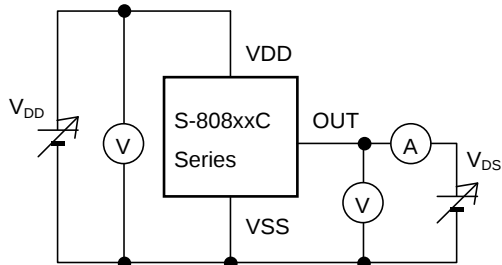


Figure 13

4.

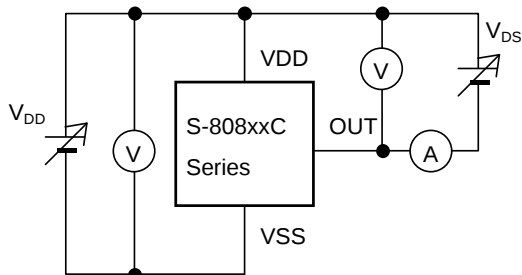
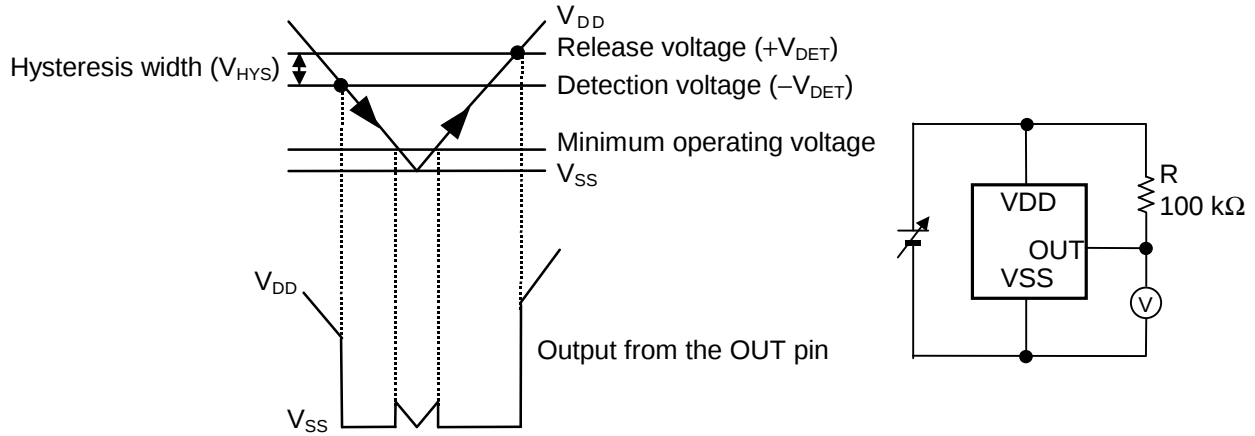


Figure 14

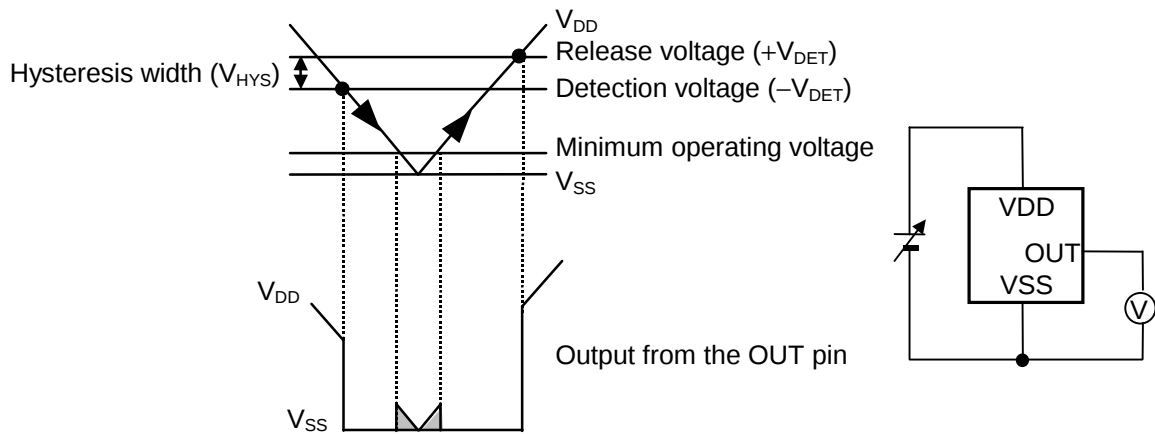
## ■ Timing Chart

### 1. Nch Open-drain Output Products



**Figure 15**

### 2. CMOS Output Products



**Remark** For values of  $V_{DD}$  less than minimum operating voltage, values of OUT terminal output is free in the shaded region.

**Figure 16**

## ■ Operation

### 1. Basic Operation: CMOS Output (Active Low)

**1-1.** When the power supply voltage ( $V_{DD}$ ) is higher than the release voltage ( $+V_{DET}$ ), the Nch transistor is OFF and the Pch transistor is ON to provide  $V_{DD}$  (high) at the output. Since the Nch transistor N1 in

**Figure 17** is OFF, the comparator input voltage is  $\frac{(R_B + R_C) \cdot V_{DD}}{R_A + R_B + R_C}$ .

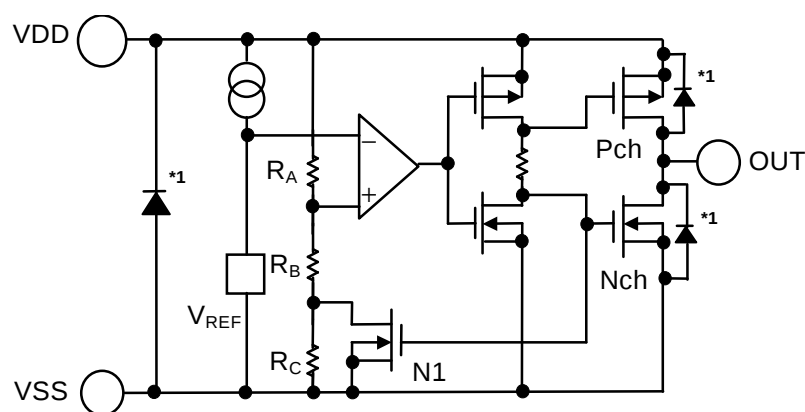
**1-2.** When the  $V_{DD}$  goes below  $+V_{DET}$ , the output provides the  $V_{DD}$  level, as long as the  $V_{DD}$  remains above the detection voltage  $-V_{DET}$ . When the  $V_{DD}$  falls below  $-V_{DET}$  (point A in **Figure 18**), the Nch transistor becomes ON, the Pch transistor becomes OFF, and the  $V_{SS}$  level appears at the output. At this time the Nch transistor N1 in **Figure 17** becomes ON, the comparator input voltage is changed to

$$\frac{R_B \cdot V_{DD}}{R_A + R_B}.$$

**1-3.** When the  $V_{DD}$  falls below the minimum operating voltage, the output becomes undefined, or goes to the  $V_{DD}$  when the output is pulled up to the  $V_{DD}$ .

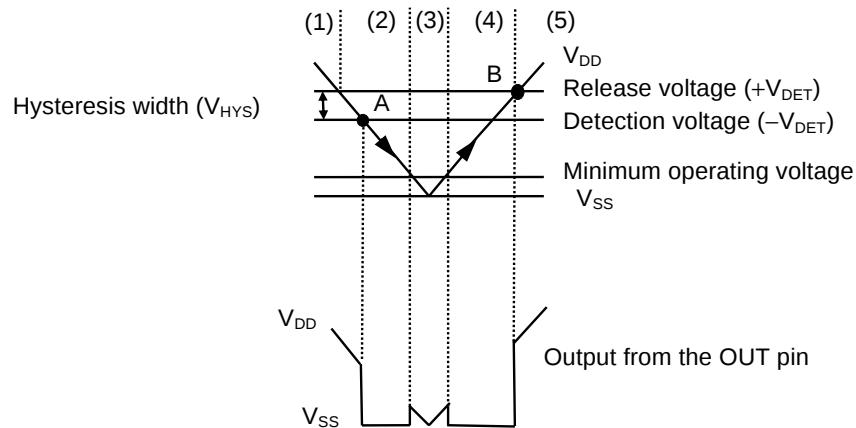
**1-4.** The  $V_{SS}$  level appears when the  $V_{DD}$  rises above the minimum operating voltage. The  $V_{SS}$  level still appears even when the  $V_{DD}$  surpasses  $-V_{DET}$ , as long as it does not exceed the release voltage  $+V_{DET}$ .

**1-5.** When the  $V_{DD}$  rises above  $+V_{DET}$  (point B in **Figure 18**), the Nch transistor becomes OFF and the Pch transistor becomes ON to provide  $V_{DD}$  level at the output.



\*1. Parasiteic diode

Figure 17 Operation 1

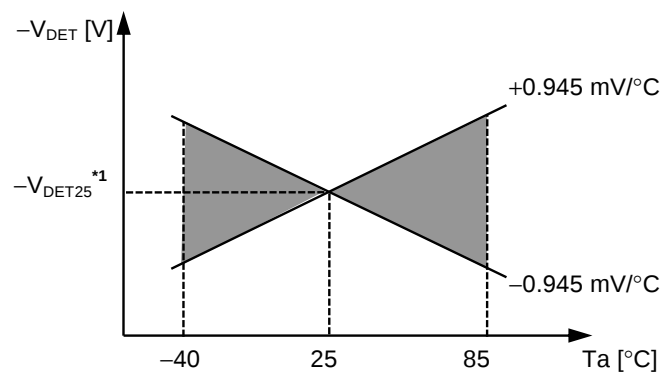


**Figure 18 Operation 2**

## 2. Other Characteristics

### 2-1. Temperature Characteristics of Detection Voltage

The shaded area in **Figure 19** shows the temperature characteristics of the detection voltage.



\*1.  $-V_{DET25}$  is an actual detection voltage value at 25°C.

**Figure 19 Temperature Characteristics of Detection Voltage (Example for S-80827C)**

### 2-2. Temperature Characteristics of Release Voltage

The temperature change  $\frac{\Delta + V_{DET}}{\Delta Ta}$  of the release voltage is calculated by using the temperature

change  $\frac{\Delta - V_{DET}}{\Delta Ta}$  of the detection voltage as follows:

$$\frac{\Delta + V_{DET}}{\Delta Ta} = \frac{+V_{DET}}{-V_{DET}} \times \frac{\Delta - V_{DET}}{\Delta Ta}$$

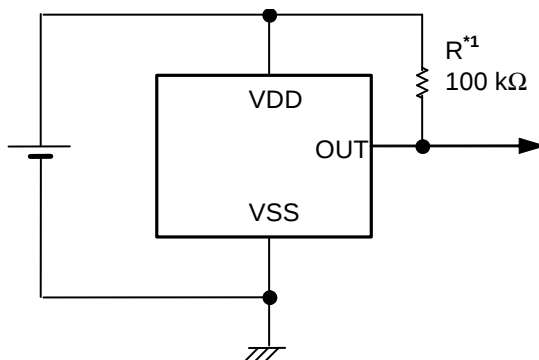
The temperature change of the release voltage and the detection voltage have the same sign consequently.

### 2-3. Temperature Characteristics of Hysteresis Voltage

The temperature change of the hysteresis voltage is expressed as  $\frac{\Delta + V_{DET}}{\Delta T_a} - \frac{\Delta - V_{DET}}{\Delta T_a}$  and is calculated as follows:

$$\frac{\Delta + V_{DET}}{\Delta T_a} - \frac{\Delta - V_{DET}}{\Delta T_a} = \frac{V_{HYS}}{-V_{DET}} \times \frac{\Delta - V_{DET}}{\Delta T_a}$$

### ■ Standard Circuit



\*1. R is unnecessary for CMOS output products.

**Figure 20**

**Caution** The above connection diagram and constants do not guarantee correct operation. Perform sufficient evaluation using the actual application to set the constants.

### ■ Technical Terms

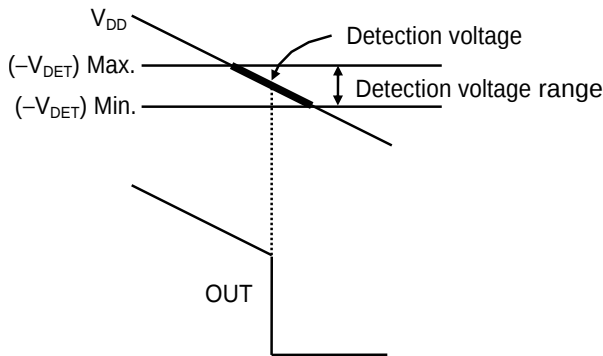
#### 1. Detection Voltage ( $-V_{DET}$ ), Release Voltage ( $+V_{DET}$ )

The detection voltage ( $-V_{DET}$ ) is a voltage at which the output turns to low. The detection voltage varies slightly among products of the same specification. The variation of detection voltage between the specified minimum ( $-V_{DET}$ ) Min. and the maximum ( $-V_{DET}$ ) Max. is called the detection voltage range (Refer to **Figure 21**).

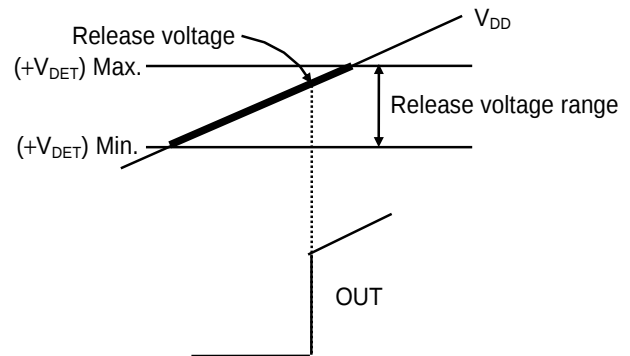
Example: For the S-80815CN, the detection voltage lies in the range of  $1.470 \leq (-V_{DET}) \leq 1.530$ .  
This means that some S-80815CNs have 1.470 V for  $-V_{DET}$  and some have 1.530 V.

The release voltage ( $+V_{DET}$ ) is a voltage at which the output turns to high. The release voltage varies slightly among products of the same specification. The variation of release voltages between the specified minimum ( $+V_{DET}$ ) Min. and the maximum ( $+V_{DET}$ ) Max. is called the release voltage range (Refer to **Figure 22**). The range is calculated from the actual detection voltage ( $-V_{DET}$ ) of a product and is expressed by  $-V_{DET} \times 1.03 \leq +V_{DET} \leq -V_{DET} \times 1.08$ .

Example: For the S-80815CN, the release voltage lies in the range of  $1.514 \leq (+V_{DET}) \leq 1.652$ .  
This means that some S-80815CNs have 1.514 V for  $+V_{DET}$  and some have 1.652 V.



**Figure 21 Detection Voltage (CMOS Output Products)**



**Figure 22 Release Voltage (CMOS Output Products)**

**Remark** Although the detection voltage and release voltage overlap in the range of 1.514 V to 1.530 V,  $+V_{DET}$  is always larger than  $-V_{DET}$ .

## 2. Hysteresis Width ( $V_{HYS}$ )

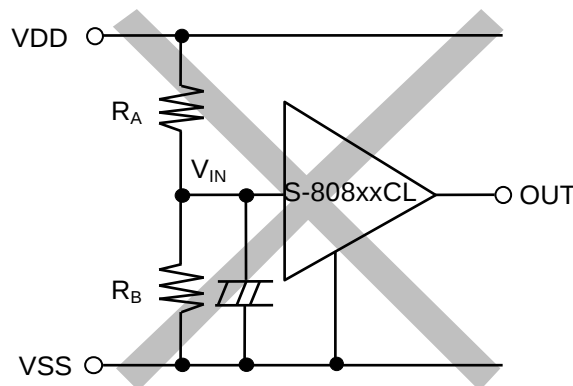
The hysteresis width is the voltage difference between the detection voltage and the release voltage (The voltage at point B – The voltage at point A =  $V_{HYS}$  in **Figure 18**). The existence of the hysteresis width prevents malfunction caused by noise on input signal.

## 3. Through-type Current

The through-type current refers to the current that flows instantaneously at the time of detection and release of a voltage detector. The through-type current is large in CMOS output products, small in Nch open-drain output products.

## 4. Oscillation

In applications where a resistor is connected to the voltage detector input (**Figure 23**), taking a CMOS active low product for example, the through-type current which is generated when the output goes from low to high (release) causes a voltage drop equal to [through-type current] × [input resistance] across the resistor. When the input voltage drops below the detection voltage ( $-V_{DET}$ ) as a result, the output voltage goes to low level. In this state, the through-type current stops and its resultant voltage drop disappears, and the output goes from low to high. A through-type current is again generated, a voltage drop appears, and repeating the process finally induces oscillation.



**Figure 23 An Example for Bad Implementation of Input Voltage Divider**

## ■ Electrical Characteristics for Customized Products

### 1. S-80824KNUA-D2BT2x, S-80824KNY-n2-U

Table 18

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                 | Condition                                                                   | Min.  | Typ.                | Max.      | Unit                  | Test circuit |
|---------------------------------------------------------|--------------------------------------------------------|-----------------------------------------------------------------------------|-------|---------------------|-----------|-----------------------|--------------|
| Detection voltage <sup>*1</sup>                         | $-V_{DET}$                                             | —                                                                           | 2.295 | 2.400 <sup>*2</sup> | 2.505     | V                     | 1            |
| Release voltage                                         | $+V_{DET}$                                             | —                                                                           | 4.300 | 4.400               | 4.500     | V                     | 1            |
| Current consumption                                     | $I_{SS}$                                               | $V_{DD}=6.0\text{ V}$                                                       | —     | 0.8                 | 2.4       | $\mu\text{A}$         | 2            |
| Operating voltage                                       | $V_{DD}$                                               | —                                                                           | 0.95  | —                   | 10.0      | V                     | 1            |
| Output current                                          | $I_{OUT}$                                              | Output transistor, $V_{DD} = 0.95\text{ V}$                                 | 0.03  | 0.24                | —         | mA                    | 3            |
|                                                         |                                                        | Nch, $V_{DS} = 0.5\text{ V}$ $V_{DD} = 1.2\text{ V}$                        | 0.23  | 0.50                | —         | mA                    | 3            |
| Leakage current                                         | $I_{LEAK}$                                             | Output transistor, Nch, $V_{DD} = 10.0\text{ V}$ , $V_{DS} = 10.0\text{ V}$ | —     | —                   | 0.1       | $\mu\text{A}$         | 3            |
| Response time                                           | $t_{PLH}$                                              | —                                                                           | —     | —                   | 60        | $\mu\text{s}$         | 1            |
| Detection voltage temperature coefficient <sup>*3</sup> | $\frac{\Delta - V_{DET}}{\Delta T_a \bullet -V_{DET}}$ | $T_a = -40\text{ to }85\text{ }^\circ\text{C}$                              | —     | $\pm 100$           | $\pm 350$ | ppm/ $^\circ\text{C}$ | 1            |

\*1.  $-V_{DET}$ : Actual detection voltage value

\*2. Specified detection voltage value ( $-V_{DET(S)}$ )

\*3. The temperature change of the detection voltage [mV/ $^\circ\text{C}$ ] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta T_a} [\text{mV}/^\circ\text{C}]^{*1} = -V_{DET(S)} (\text{Typ.}) [\text{V}]^{*2} \times \frac{\Delta - V_{DET}}{\Delta T_a \bullet -V_{DET}} [\text{ppm}/^\circ\text{C}]^{*3} \div 1000$$

\*1. Temperature change of the detection voltage

\*2. Specified detection voltage

\*3. Detection voltage temperature coefficient

**2. S-80844KLUA-D2AT2x, S-80844KLY-n2-U**

**Table 19**

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                | Condition                                       |                         | Min.  | Typ.                | Max.  | Unit   | Test circuit |
|---------------------------------------------------------|-------------------------------------------------------|-------------------------------------------------|-------------------------|-------|---------------------|-------|--------|--------------|
| Detection voltage <sup>*1</sup>                         | −V <sub>DET</sub>                                     | —                                               |                         | 4.295 | 4.450 <sup>*2</sup> | 4.605 | V      | 1            |
| Release voltage                                         | +V <sub>DET</sub>                                     | —                                               |                         | —     | —                   | 4.700 | V      | 1            |
| Current consumption                                     | I <sub>SS</sub>                                       | V <sub>DD</sub> = 6.0 V                         |                         | —     | 1.0                 | 3.0   | μA     | 2            |
| Operating voltage                                       | V <sub>DD</sub>                                       | —                                               |                         | 0.95  | —                   | 10.0  | V      | 1            |
| Output current                                          | I <sub>OUT</sub>                                      | Output transistor, Nch, V <sub>DS</sub> = 0.5 V | V <sub>DD</sub> = 1.2 V | 0.23  | 0.50                | —     | mA     | 3            |
|                                                         |                                                       |                                                 | V <sub>DD</sub> = 2.4 V | 1.60  | 3.70                | —     | mA     | 3            |
|                                                         |                                                       | Output transistor, Pch, V <sub>DS</sub> = 0.5 V | V <sub>DD</sub> = 4.8 V | 0.36  | 0.62                | —     | mA     | 4            |
| Response time                                           | t <sub>PLH</sub>                                      | —                                               |                         | —     | —                   | 60    | μs     | 1            |
| Detection voltage temperature coefficient <sup>*3</sup> | $\frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}}$ | Ta = −40 to 85 °C                               |                         | —     | ±100                | ±350  | ppm/°C | 1            |

\*1.  $-V_{DET}$ : Actual detection voltage value

\*2. Specified detection voltage value ( $-V_{DET(S)}$ )

\*3. The temperature change of the detection voltage [mV/°C] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta T_a} [\text{mV/°C}]^{*1} = -V_{DET(S)}(\text{Typ.})[\text{V}]^{*2} \times \frac{\Delta - V_{DET}}{\Delta T_a \bullet -V_{DET}} [\text{ppm/°C}]^{*3} \div 1000$$

\*1. Temperature change of the detection voltage

\*2. Specified detection voltage

\*3. Detection voltage temperature coefficient

**3. S-80846KNUA-D2CT2x, S-80846KNY-n2-U**

**Table 20**

(Ta = 25 °C unless otherwise specified)

| Item                                                    | Symbol                                                | Condition                                                                   | Min.  | Typ.                | Max.  | Unit   | Test circuit |
|---------------------------------------------------------|-------------------------------------------------------|-----------------------------------------------------------------------------|-------|---------------------|-------|--------|--------------|
| Detection voltage <sup>*1</sup>                         | $-V_{DET}$                                            | —                                                                           | 4.500 | 4.600 <sup>*2</sup> | 4.700 | V      | 1            |
| Hysteresis width                                        | $V_{HYS}$                                             | —                                                                           | —     | 0.05                | 0.10  | V      | 1            |
| Current consumption                                     | $I_{SS}$                                              | $V_{DD} = 6.0\text{ V}$                                                     | —     | 0.9                 | 2.7   | μA     | 2            |
| Operating voltage                                       | $V_{DD}$                                              | —                                                                           | 0.95  | —                   | 10.0  | V      | 1            |
| Output current                                          | $I_{OUT}$                                             | Output transistor, $V_{DD} = 1.2\text{ V}$                                  | 0.59  | 1.36                | —     | mA     | 3            |
|                                                         |                                                       | Nch, $V_{DS} = 0.5\text{ V}$ $V_{DD} = 2.4\text{ V}$                        | 2.88  | 4.98                | —     | mA     | 3            |
| Leakage current                                         | $I_{LEAK}$                                            | Output transistor, Nch, $V_{DD} = 10.0\text{ V}$ , $V_{DS} = 10.0\text{ V}$ | —     | —                   | 0.1   | μA     | 3            |
| Response time                                           | $t_{PLH}$                                             | —                                                                           | —     | —                   | 60    | μs     | 1            |
| Detection voltage temperature coefficient <sup>*3</sup> | $\frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}}$ | $Ta = -40\text{ to }85\text{ °C}$                                           | —     | ±100                | ±350  | ppm/°C | 1            |

**\*1.**  $-V_{DET}$ : Actual detection voltage value

**\*2.** Specified detection voltage value ( $-V_{DET(S)}$ )

**\*3.** The temperature change of the detection voltage [mV/°C] is calculated by using the following equation.

$$\frac{\Delta - V_{DET}}{\Delta Ta} [\text{mV/°C}]^{*1} = -V_{DET(S)}(\text{Typ.})[V]^{*2} \times \frac{\Delta - V_{DET}}{\Delta Ta \bullet -V_{DET}} [\text{ppm/°C}]^{*3} \div 1000$$

**\*1.** Temperature change of the detection voltage

**\*2.** Specified detection voltage

**\*3.** Detection voltage temperature coefficient

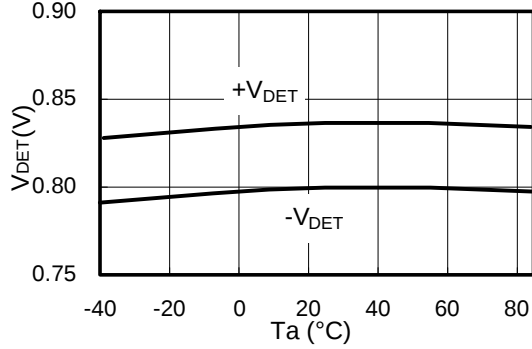
**■ Precautions**

- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- In CMOS output products of the S-808xxC series, the through-type current flows at the detection and the release. If the input impedance is high, oscillation may occur due to the voltage drop by the through-type current during releasing.
- In CMOS output products oscillation may occur when a pull-down resistor is used, and falling speed of the power supply voltage ( $V_{DD}$ ) is slow near the detection voltage.
- When designing for mass production using an application circuit described herein, the product deviation and temperature characteristics should be taken into consideration. SII shall not bear any responsibility for the products on the circuits described herein.
- SII claims no responsibility for any and all disputes arising out of or in connection with any infringement of the products including this IC upon patents owned by a third party.

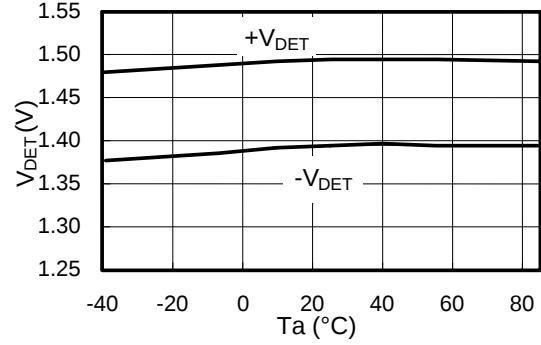
■ **Typical Characteristics (Typical Data)**

**1. Detection Voltage ( $V_{DET}$ ) - Temperature ( $T_a$ )**

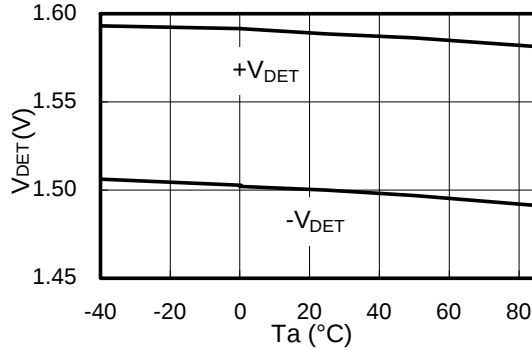
S-80808CL



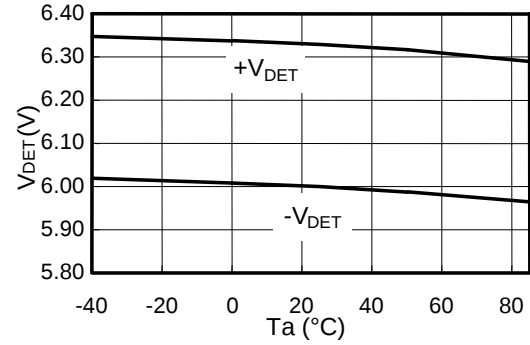
S-80814CL



S-80815CL

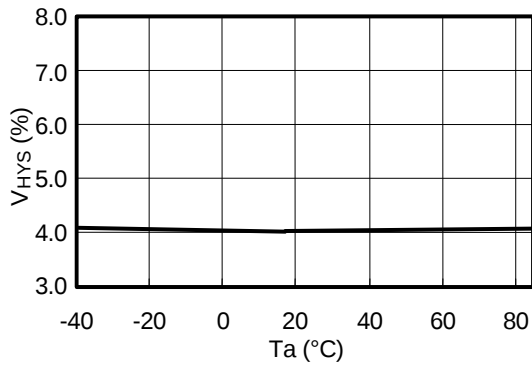


S-80860CL

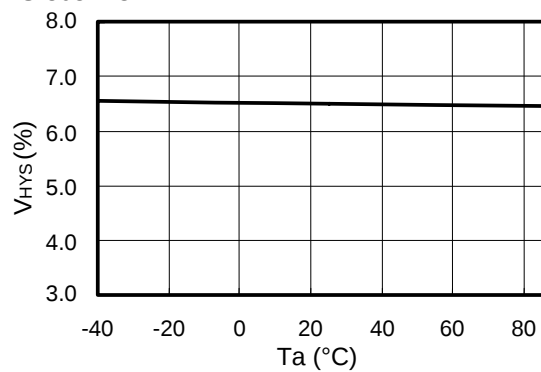


**2. Hysteresis Voltage Width ( $V_{HYS}$ ) - Temperature ( $T_a$ )**

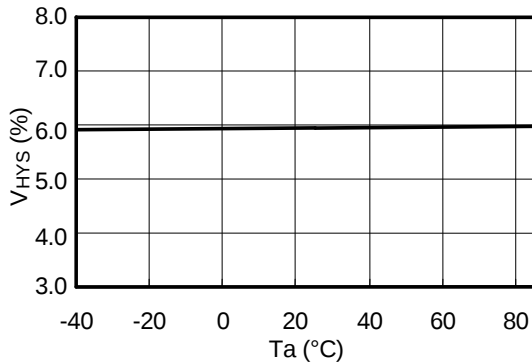
S-80808CL



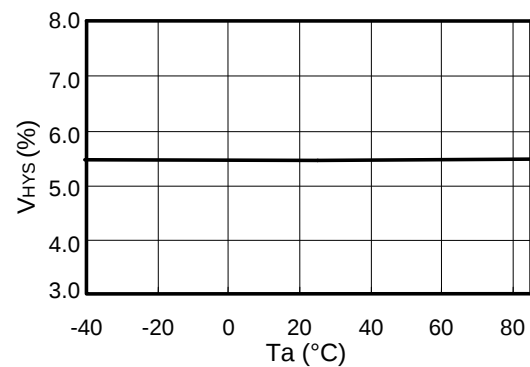
S-80814CL



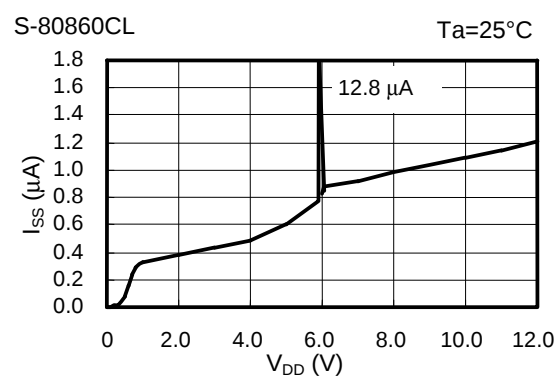
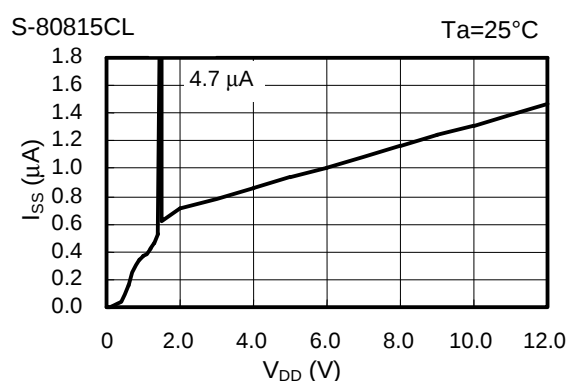
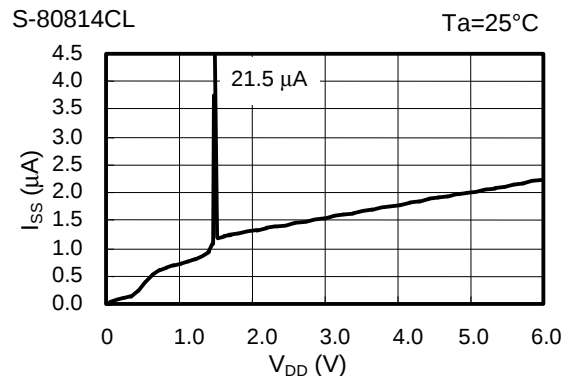
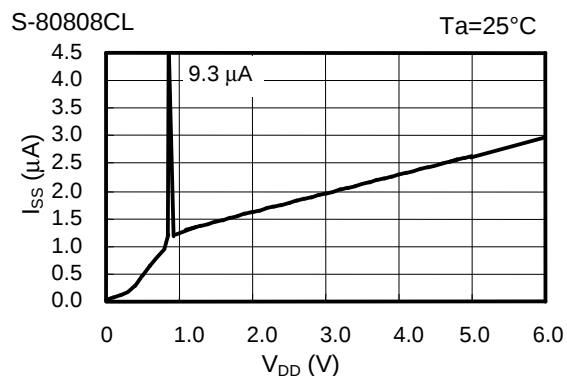
S-80815CL



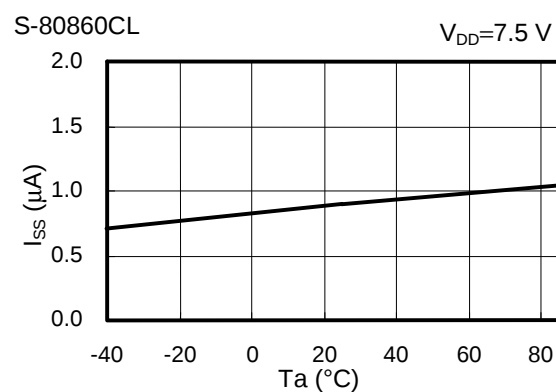
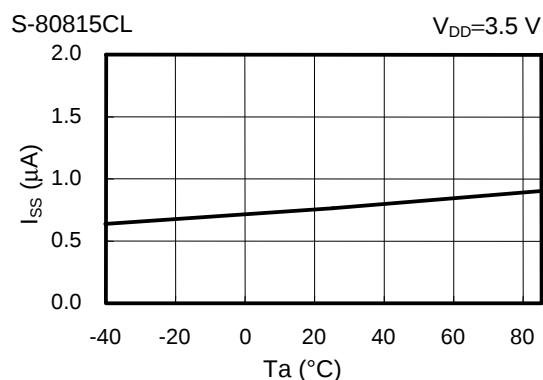
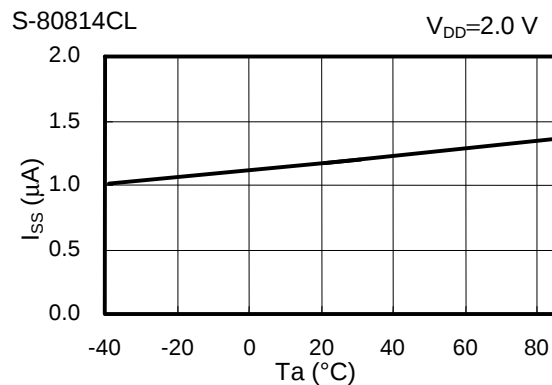
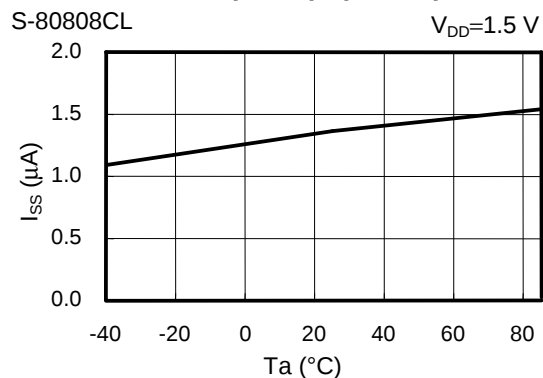
S-80860CL



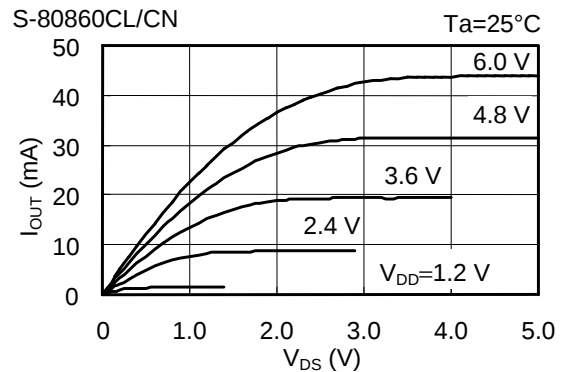
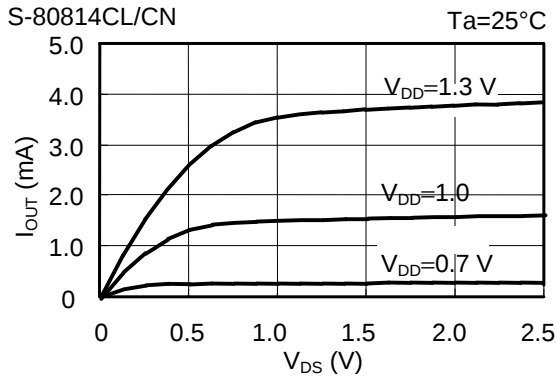
### 3. Current Consumption ( $I_{SS}$ ) - Input Voltage ( $V_{DD}$ )



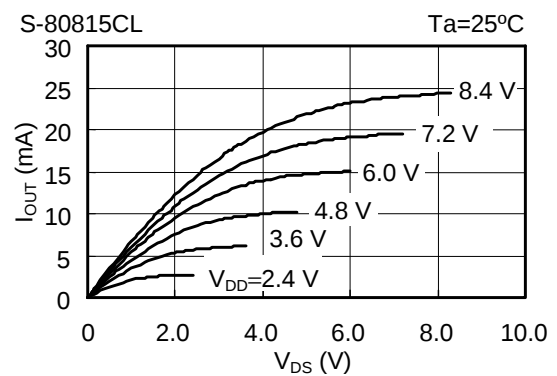
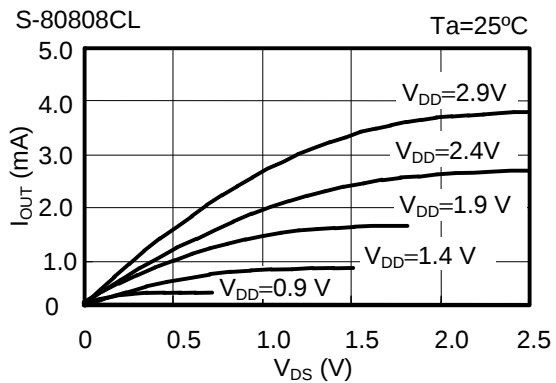
### 4. Current Consumption ( $I_{SS}$ ) - Temperature ( $T_a$ )



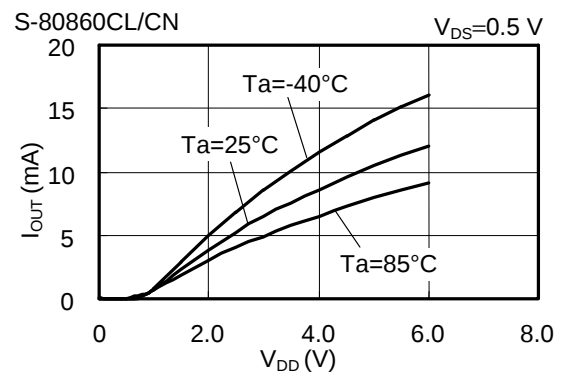
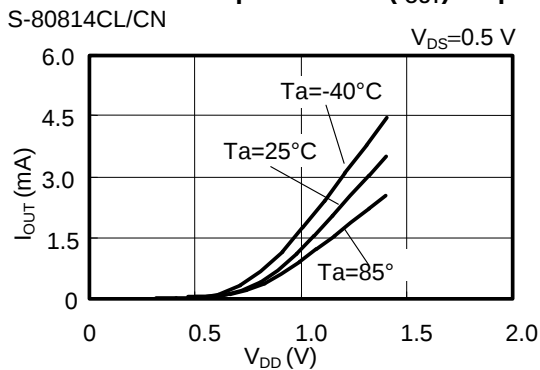
**5. Nch Transistor Output Current ( $I_{OUT}$ ) -  $V_{DS}$**



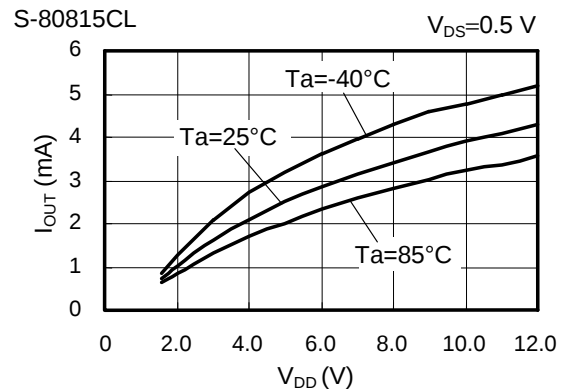
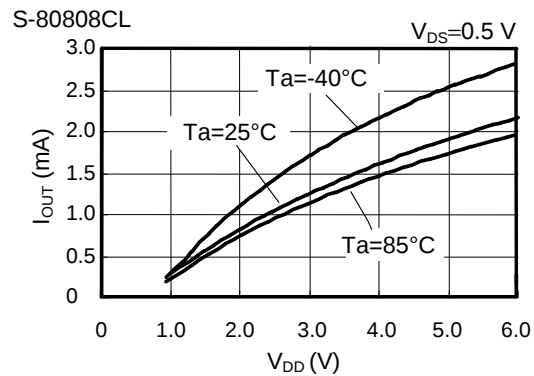
**6. Pch Transistor Output Current ( $I_{OUT}$ ) -  $V_{DS}$**



**7. Nch Transistor Output Current ( $I_{OUT}$ ) - Input Voltage ( $V_{DD}$ )**



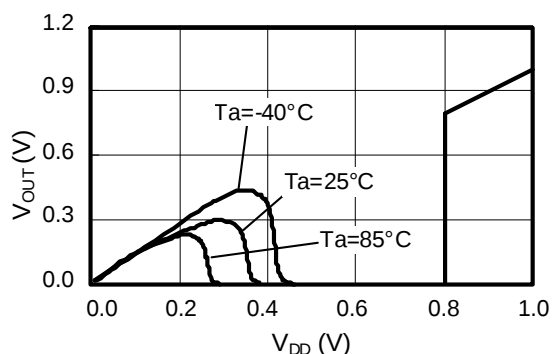
**8. Pch Transistor Output Current ( $I_{OUT}$ ) - Input Voltage ( $V_{DD}$ )**



**9. Minimum Operating Voltage - Input Voltage ( $V_{DD}$ )**

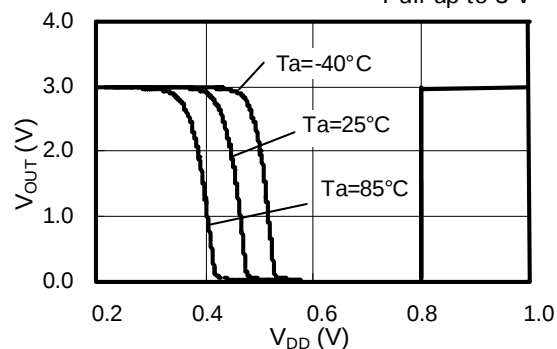
S-80808CN

Pull-up to  $V_{DD}$  100 k $\Omega$



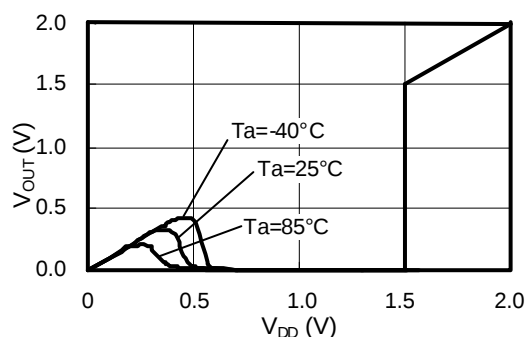
S-80808CN

Pull-up to 3 V



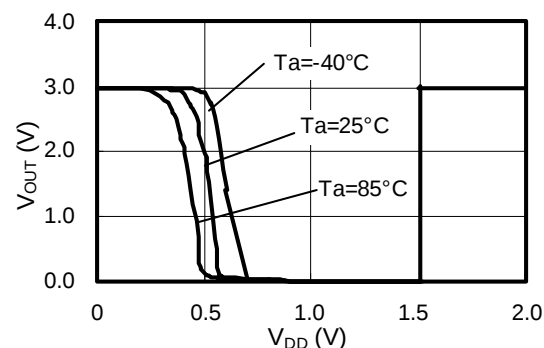
S-80815CN

Pull-up to  $V_{DD}$  100 k $\Omega$



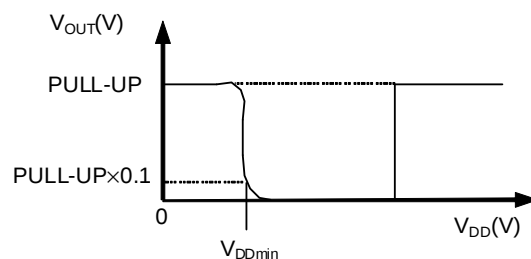
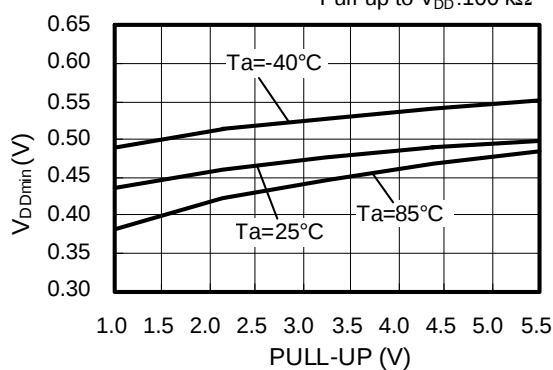
S-80815CN

Pull-up to 3 V



S-80808CN

Pull-up to  $V_{DD}$ :100 k $\Omega$

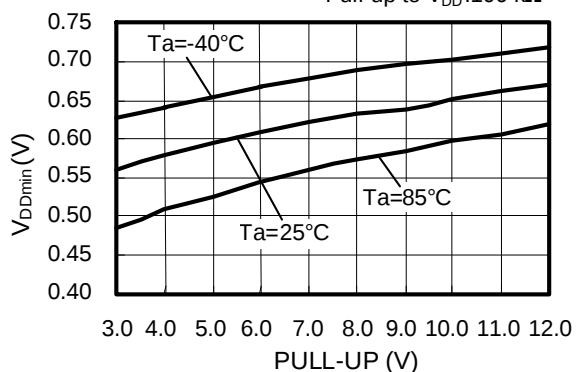


**Remark**  $V_{DDmin}$  is defined by the  $V_{DD}$  voltage at which  $V_{OUT}$  goes below 10% of PULL-UP voltage when the  $V_{DD}$  increase from 0 V.

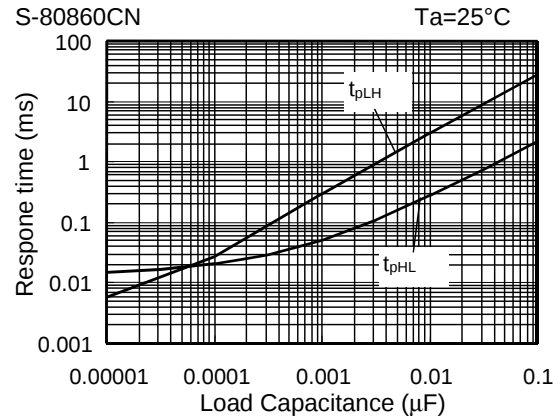
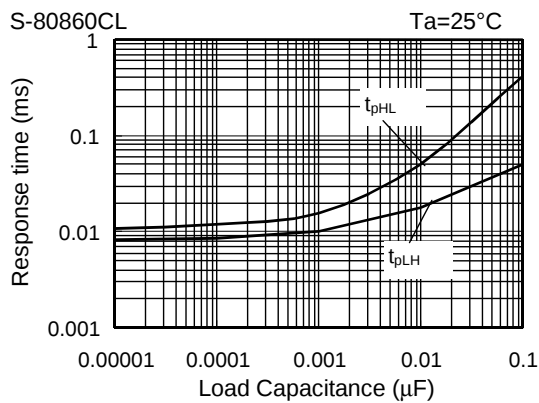
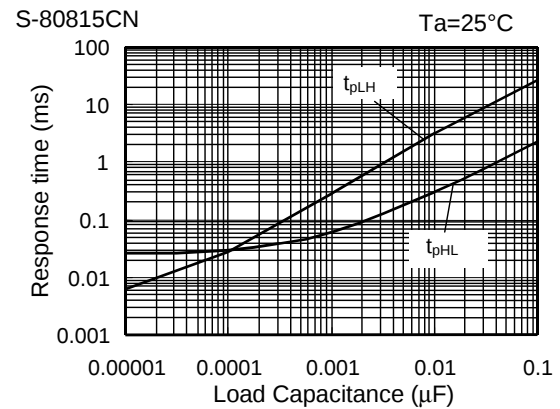
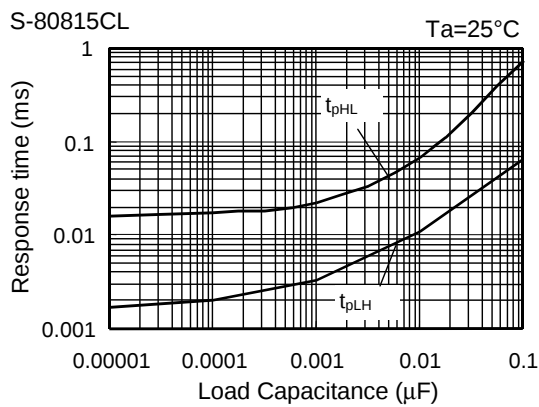
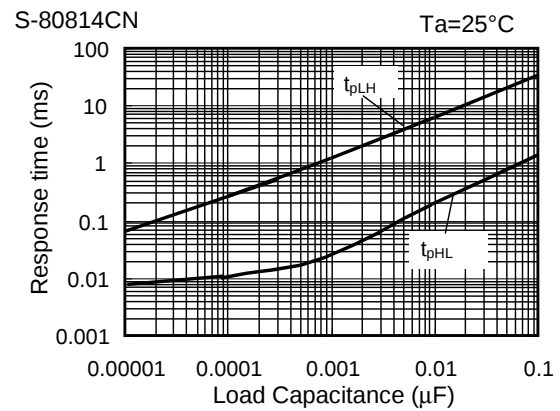
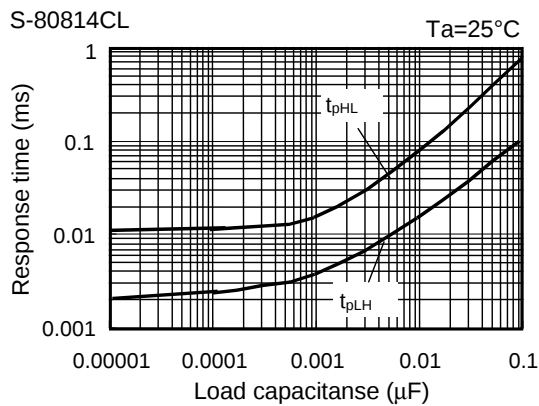
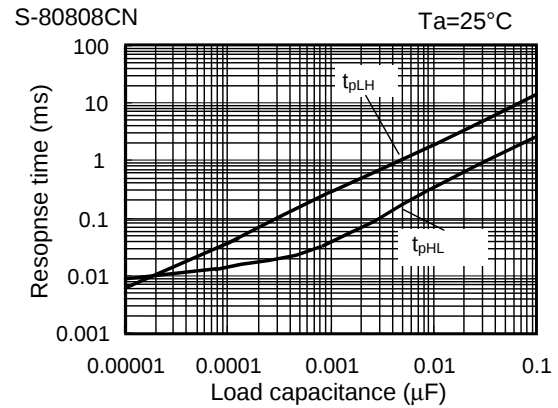
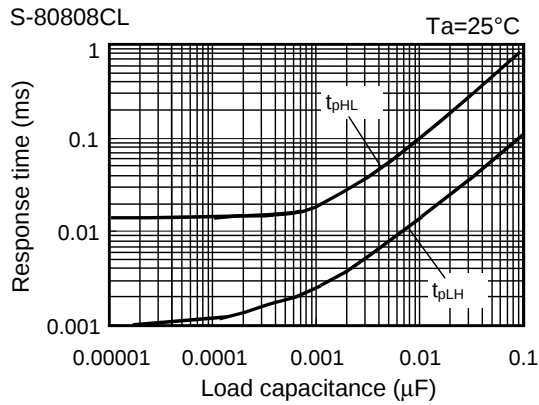
**Figure 24**

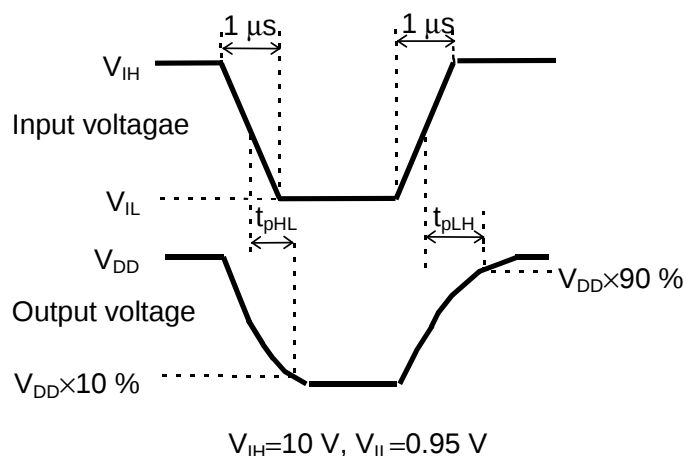
S-80815CN

Pull-up to  $V_{DD}$ :100 k $\Omega$

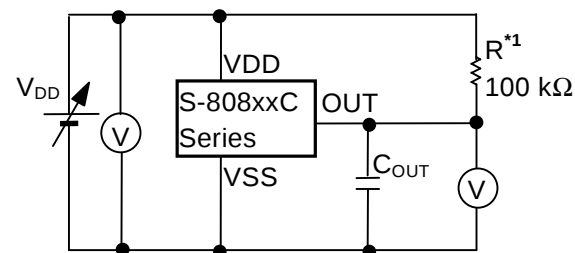


**10. Dynamic Response -  $C_{OUT}$**





**Figure 25 Measurement Condition for Response Time**



\*1. R is unnecessary for CMOS output products.

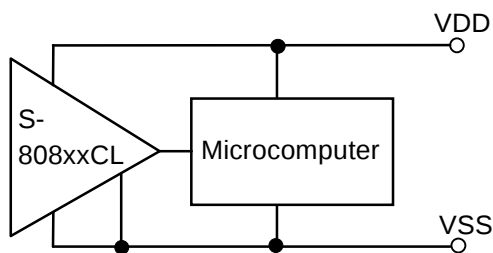
**Figure 26 Measurement Circuit for Response Time**

**Caution** The above connection diagram and constants do not guarantee correct operation. Perform sufficient evaluation using the actual application to set the constants.

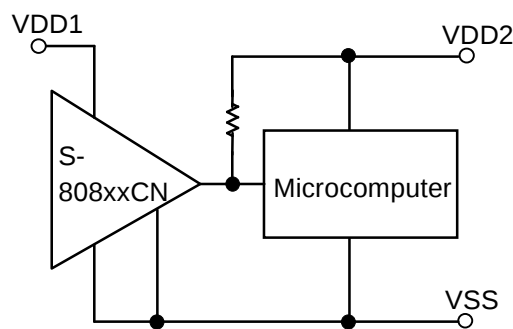
## ■ Application Circuit Examples

### 1. Microcomputer Reset Circuits

If the power supply voltage to a microcomputer falls below the specified level, an unspecified operation may be performed or the contents of the memory register may be lost. When power supply voltage returns to normal, the microcomputer needs to be initialized before normal operations can be done. Reset circuits protect microcomputers in the event of current being momentarily switched off or lowered. Reset circuits shown in **Figures 27 to 28** can be easily constructed with the help of the S-808xxC series, that has low operating voltage, a high-precision detection voltage and hysteresis.



**Figure 27 Reset Circuit Example (S-808xxCL)**



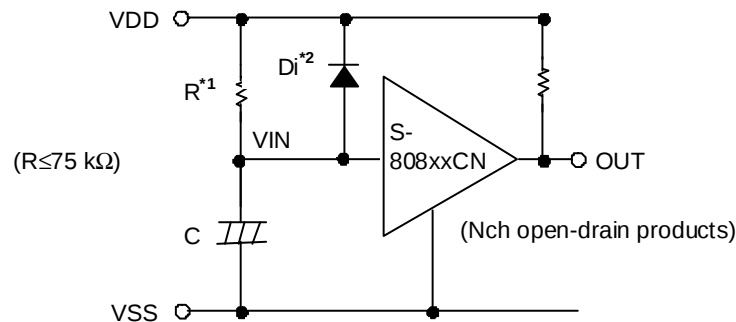
(Only for Nch open-drain products)

**Figure 28 Reset Circuit Example (S-808xxCN)**

**Caution** The above connection diagram and constants do not guarantee correct operation. Perform sufficient evaluation using the actual application to set the constants.

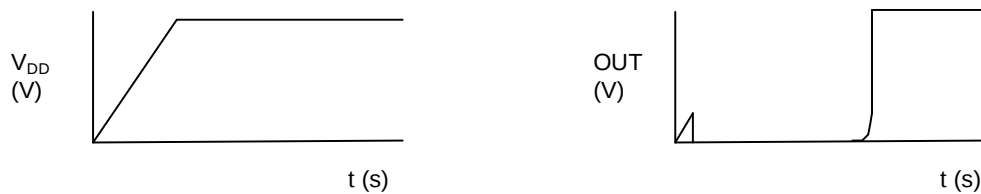
## 2. Power-on Reset Circuit

A power-on reset circuit can be constructed using Nch open-drain output product of S-808xxC Series.



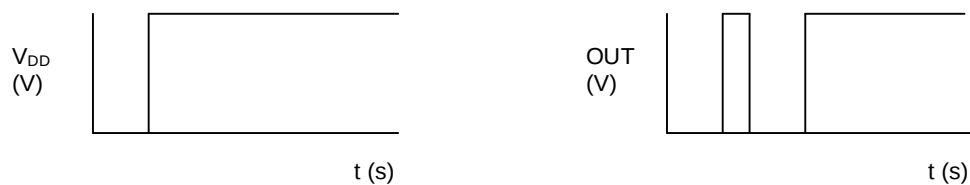
- \*1. Resistor R should be 75 kΩ or less to prevent oscillation.
- \*2. Diode Di instantaneously discharges the charge stored in the capacitor (C) at the power falling, Di can be removed when the delay of the falling time is not important.

**Figure 29**



**Figure 30**

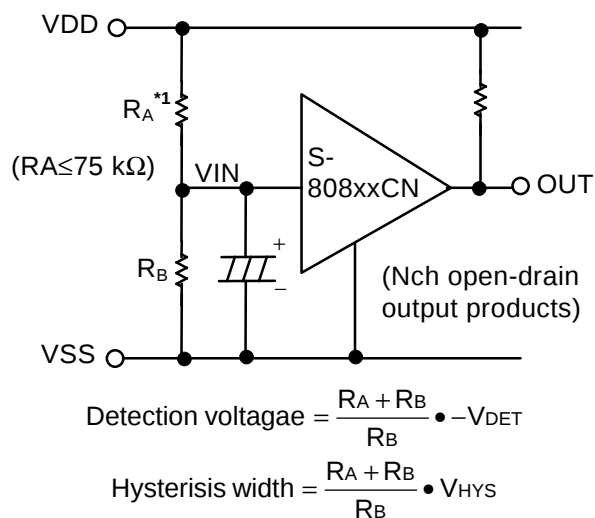
**Remark** When the power rises sharply as shown in the **Figure 31** left, the output may goes to the high level for an instant in the undefined region where the output voltage is undefined since the power voltage is less than the minimum operation voltage.



**Figure 31**

### 3. Change of Detection Voltage

In Nch open-drain output products of the S-808xxC series, detection voltage can be changed using resistance dividers or diodes as shown in **Figures 32 to 33**. In **Figure 32**, hysteresis width also changes.



\*1.  $R_A$  should be 75 kΩ or less to prevent oscillation.

**Caution** If  $R_A$  and  $R_B$  are large, the hysteresis width may also be larger than the value given by the above equation due to the through-type current (which flows slightly in an Nch open-drain product).

Figure 32

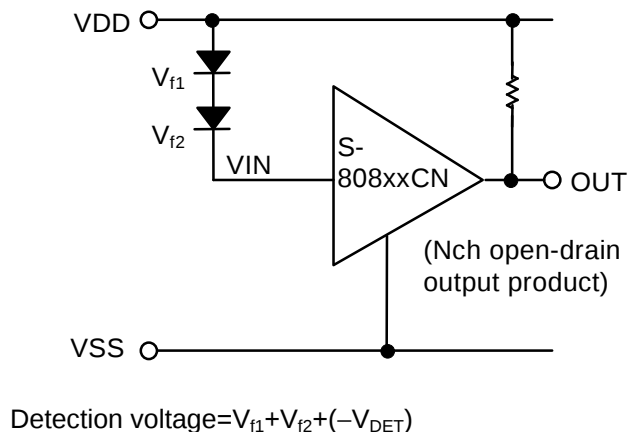
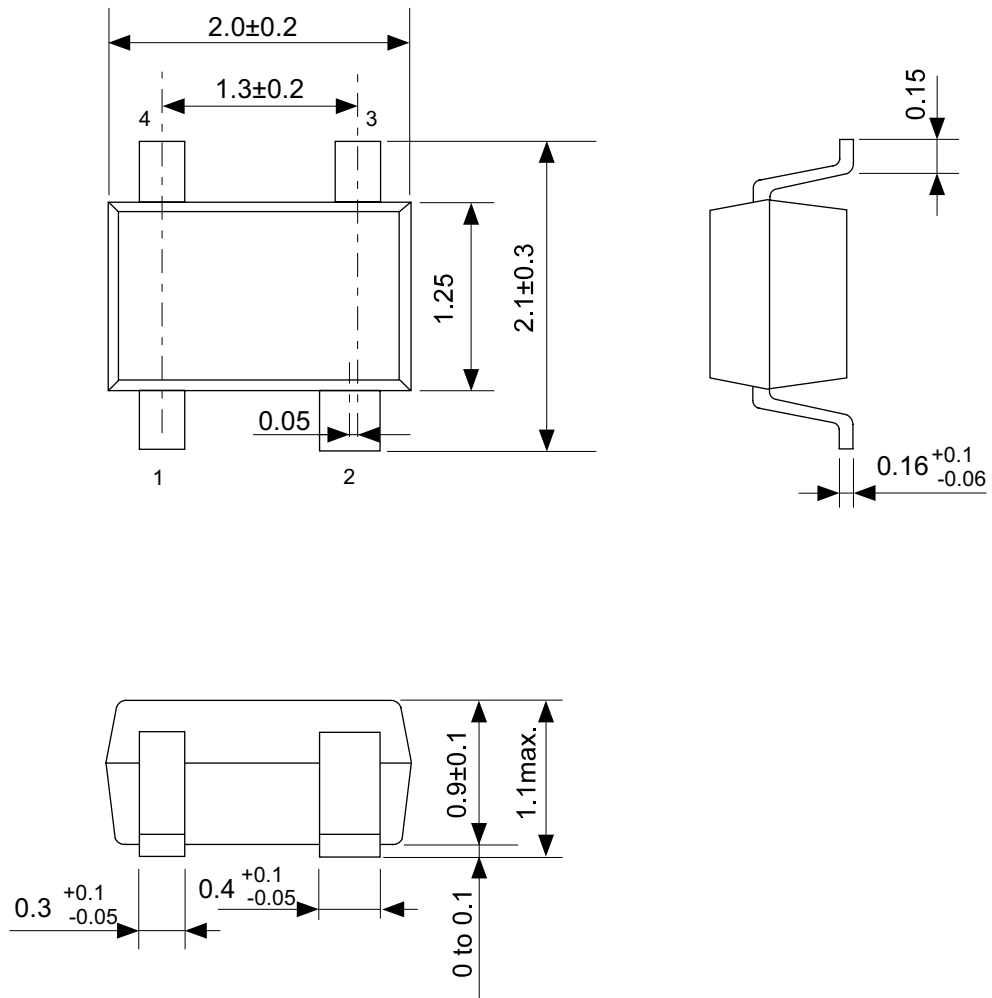


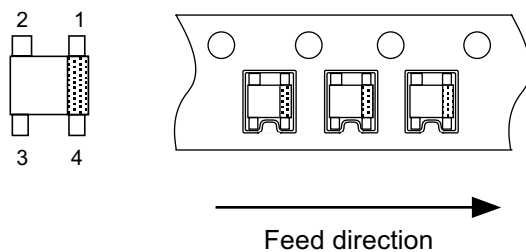
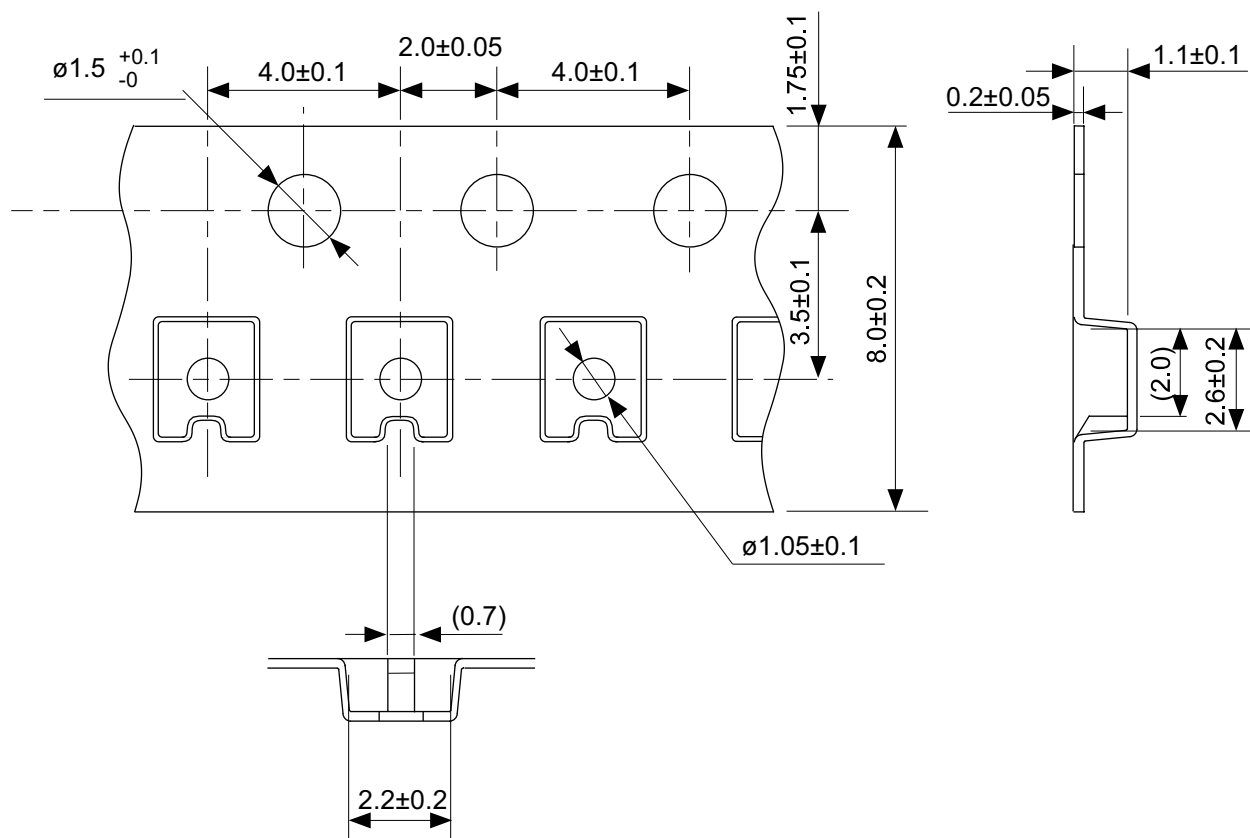
Figure 33

**Caution** The above connection diagram and constants do not guarantee correct operation. Perform sufficient evaluation using the actual application to set the constants.



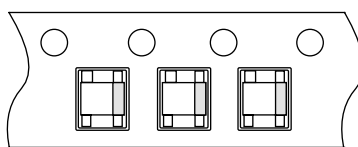
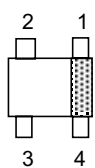
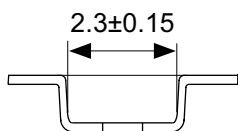
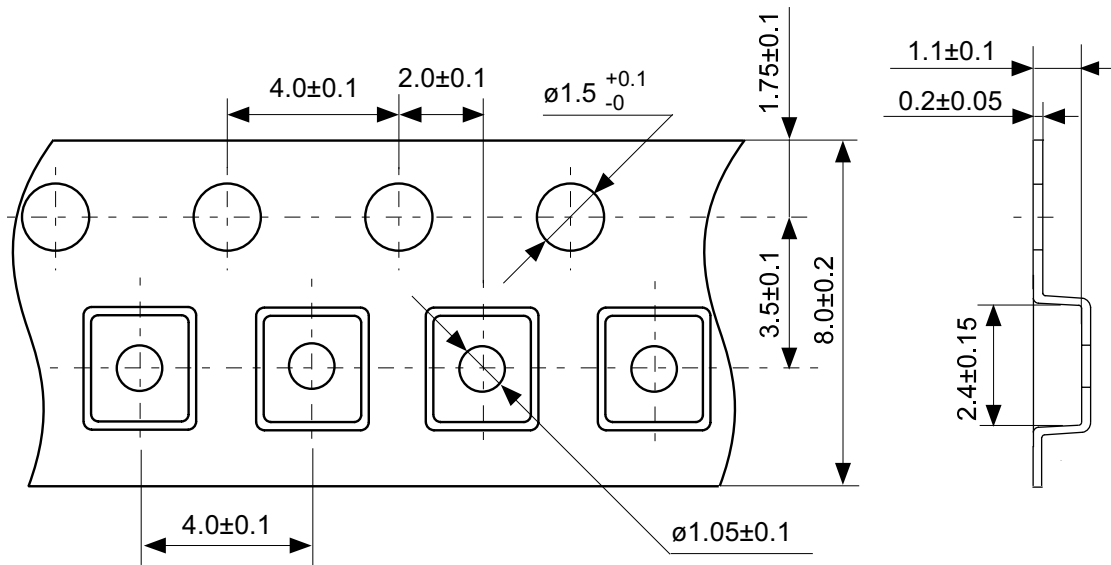
No. NP004-A-P-SD-1.1

|                        |                         |
|------------------------|-------------------------|
| TITLE                  | SC82AB-A-PKG Dimensions |
| No.                    | NP004-A-P-SD-1.1        |
| SCALE                  |                         |
| UNIT                   | mm                      |
|                        |                         |
| Seiko Instruments Inc. |                         |



No. NP004-A-C-SD-3.0

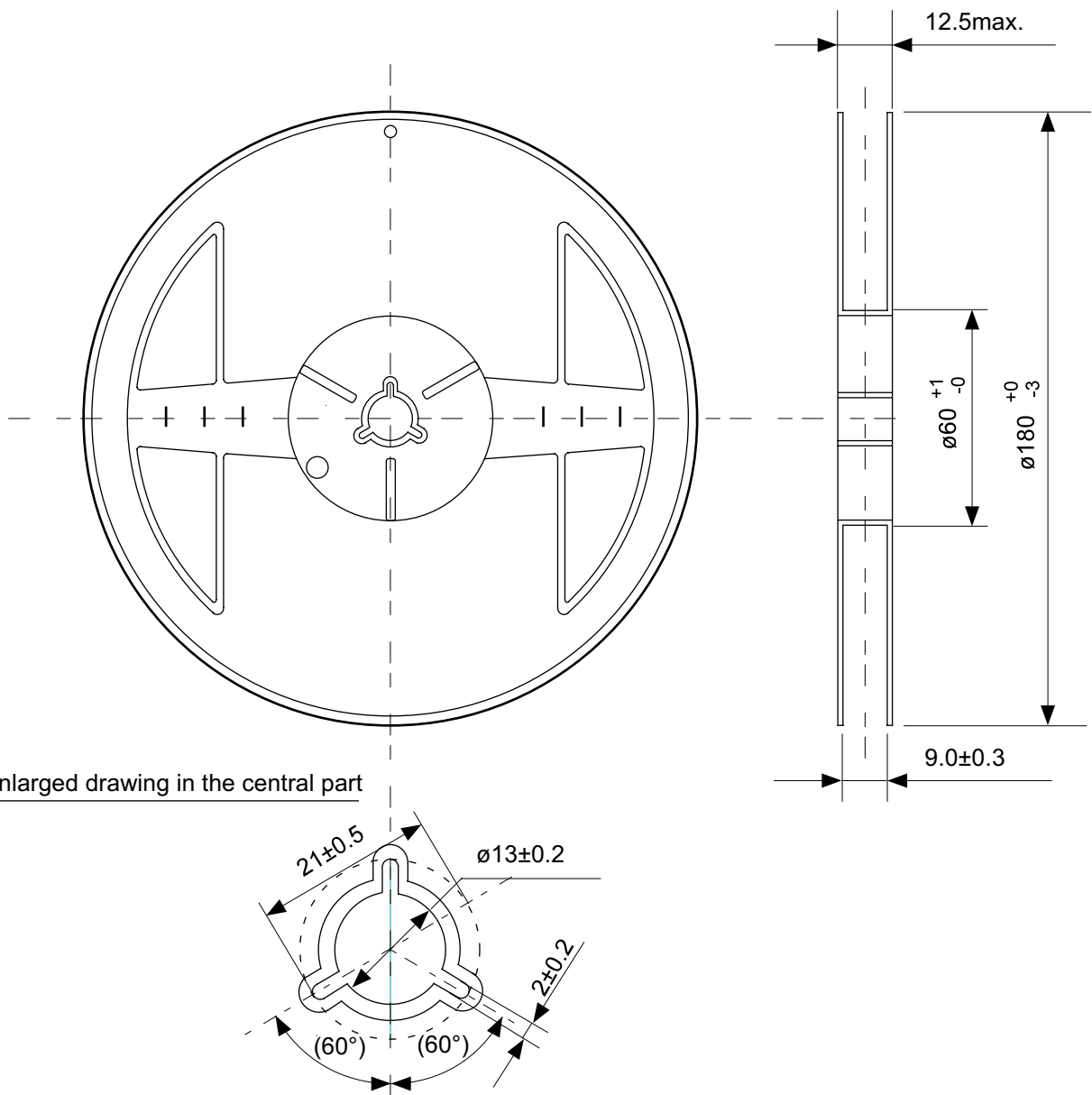
|                        |                       |
|------------------------|-----------------------|
| TITLE                  | SC82AB-A-Carrier Tape |
| No.                    | NP004-A-C-SD-3.0      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |



Feed direction

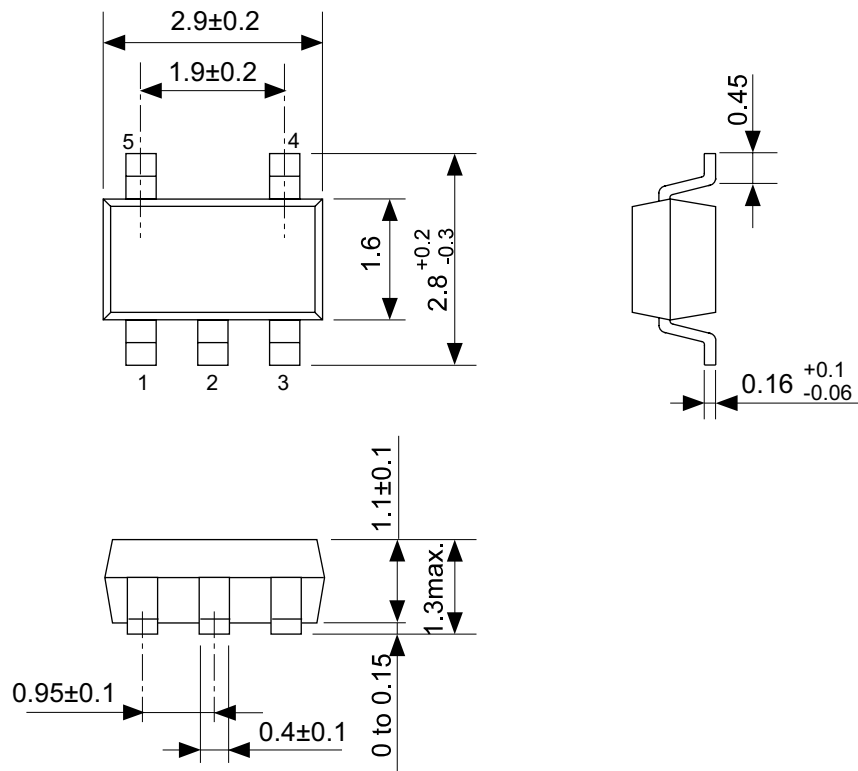
No. NP004-A-C-S1-2.0

|                        |                       |
|------------------------|-----------------------|
| TITLE                  | SC82AB-A-Carrier Tape |
| No.                    | NP004-A-C-S1-2.0      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |



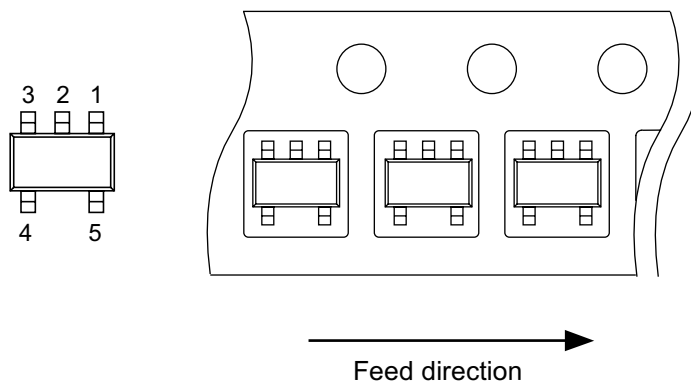
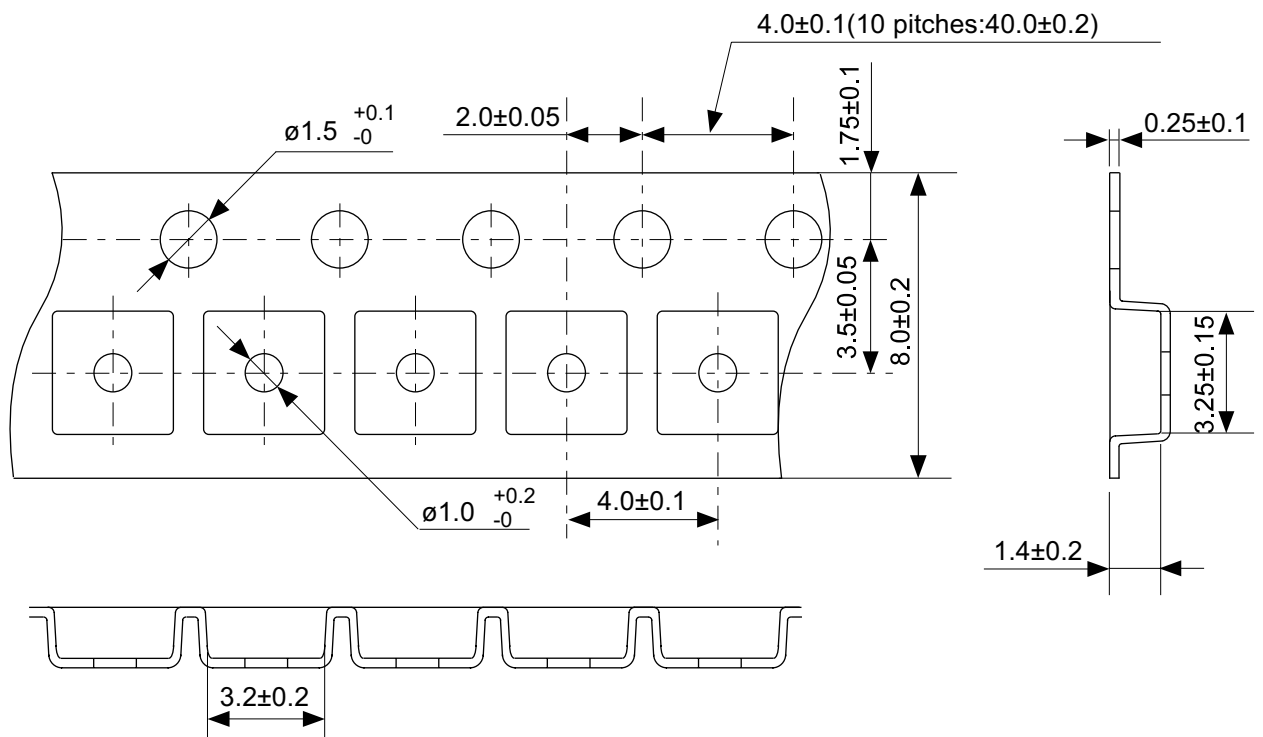
No. NP004-A-R-SD-1.1

|                        |                  |      |       |
|------------------------|------------------|------|-------|
| TITLE                  | SC82AB-A-Reel    |      |       |
| No.                    | NP004-A-R-SD-1.1 |      |       |
| SCALE                  |                  | QTY. | 3,000 |
| UNIT                   | mm               |      |       |
|                        |                  |      |       |
| Seiko Instruments Inc. |                  |      |       |



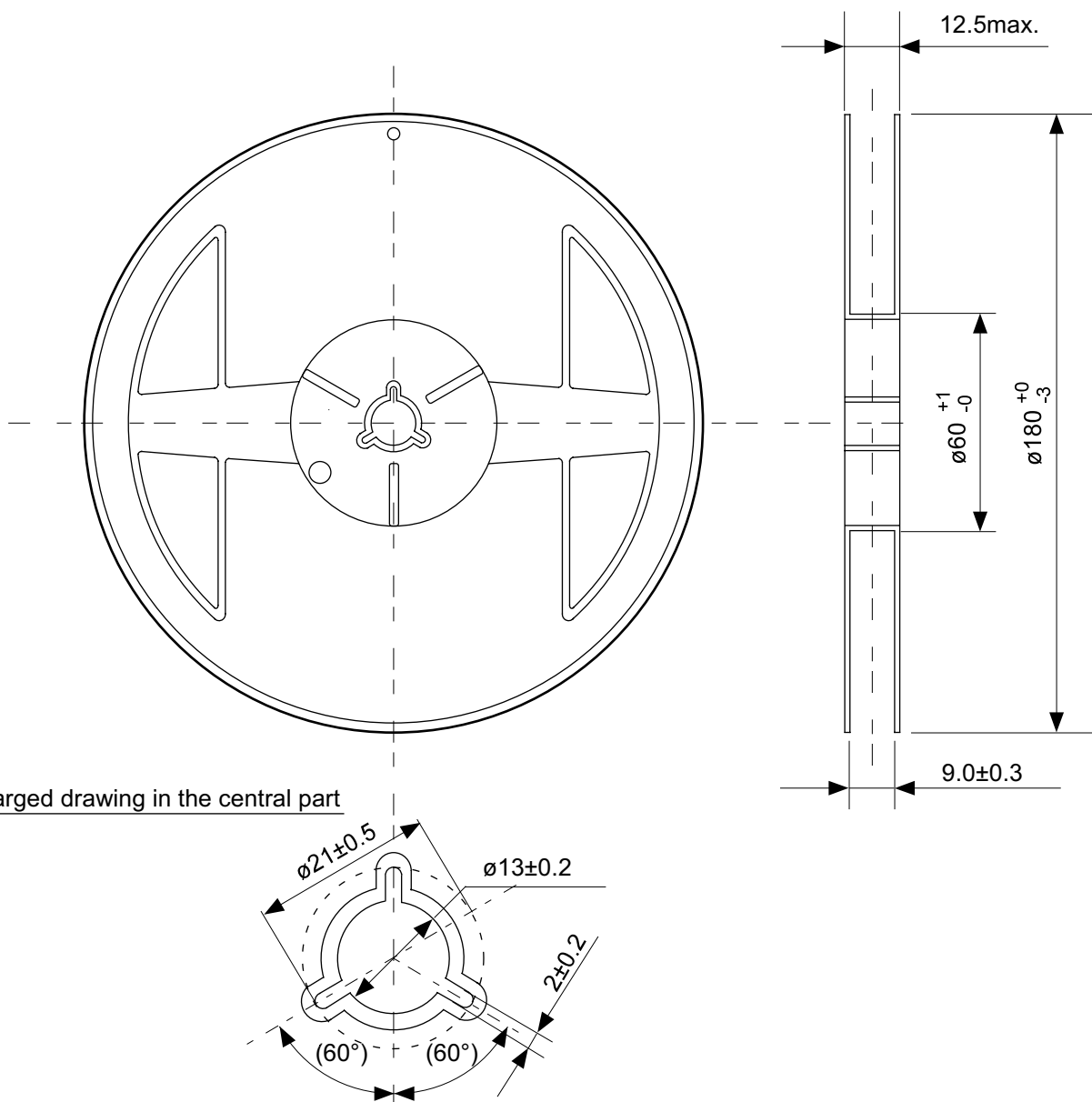
No. MP005-A-P-SD-1.2

|                        |                         |
|------------------------|-------------------------|
| TITLE                  | SOT235-A-PKG Dimensions |
| No.                    | MP005-A-P-SD-1.2        |
| SCALE                  |                         |
| UNIT                   | mm                      |
|                        |                         |
| Seiko Instruments Inc. |                         |



No. MP005-A-C-SD-2.1

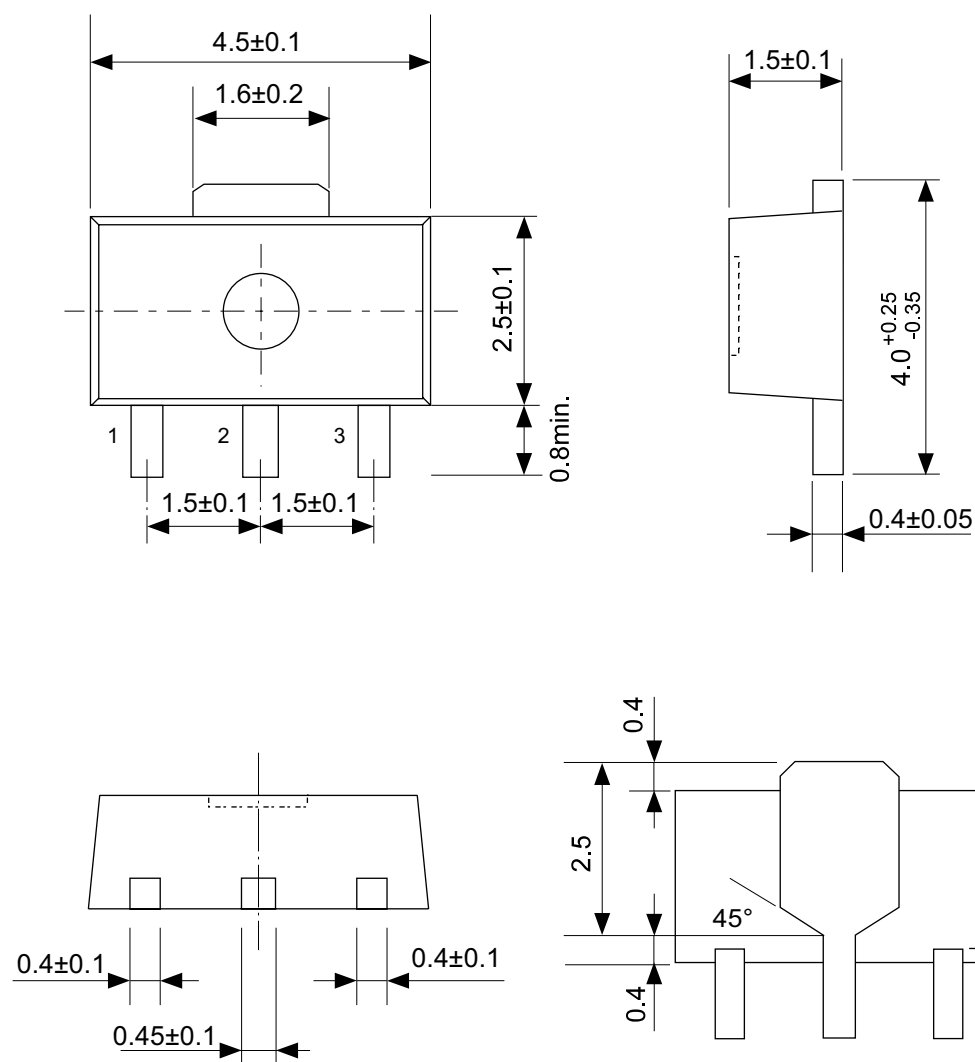
|                        |                       |
|------------------------|-----------------------|
| TITLE                  | SOT235-A-Carrier Tape |
| No.                    | MP005-A-C-SD-2.1      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |



Enlarged drawing in the central part

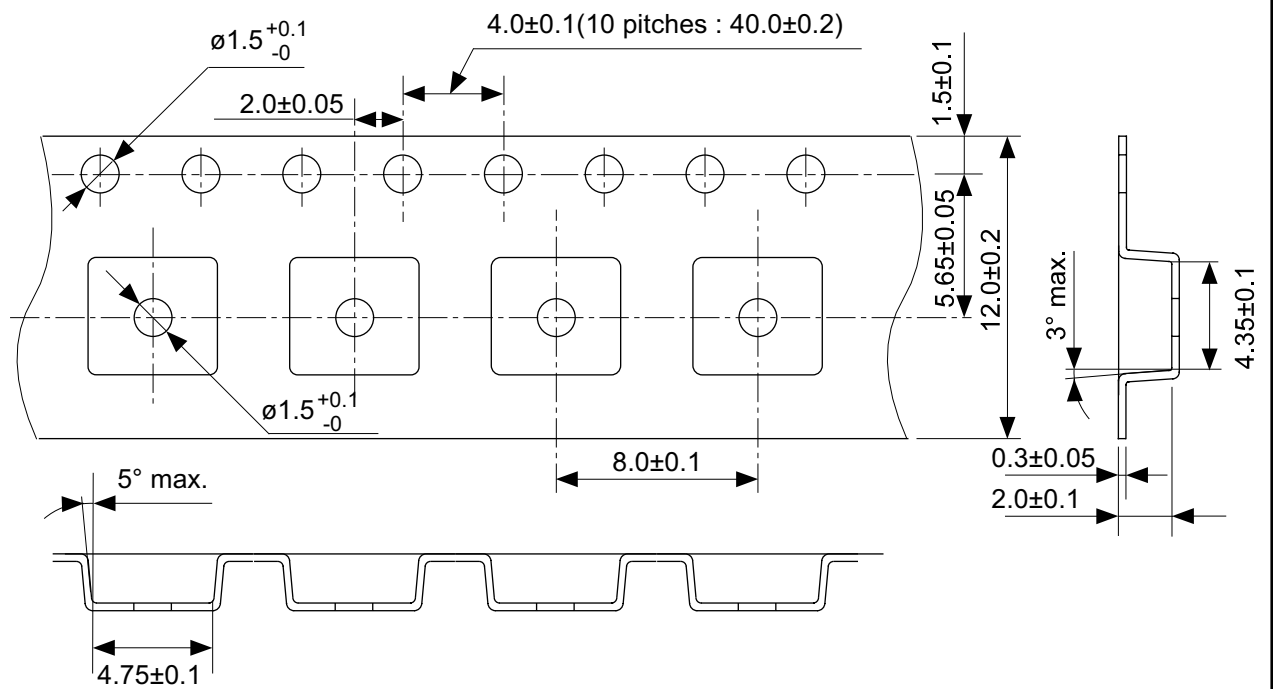
No. MP005-A-R-SD-1.1

|                        |                  |      |       |
|------------------------|------------------|------|-------|
| TITLE                  | SOT235-A-Reel    |      |       |
| No.                    | MP005-A-R-SD-1.1 |      |       |
| SCALE                  |                  | QTY. | 3,000 |
| UNIT                   | mm               |      |       |
|                        |                  |      |       |
| Seiko Instruments Inc. |                  |      |       |



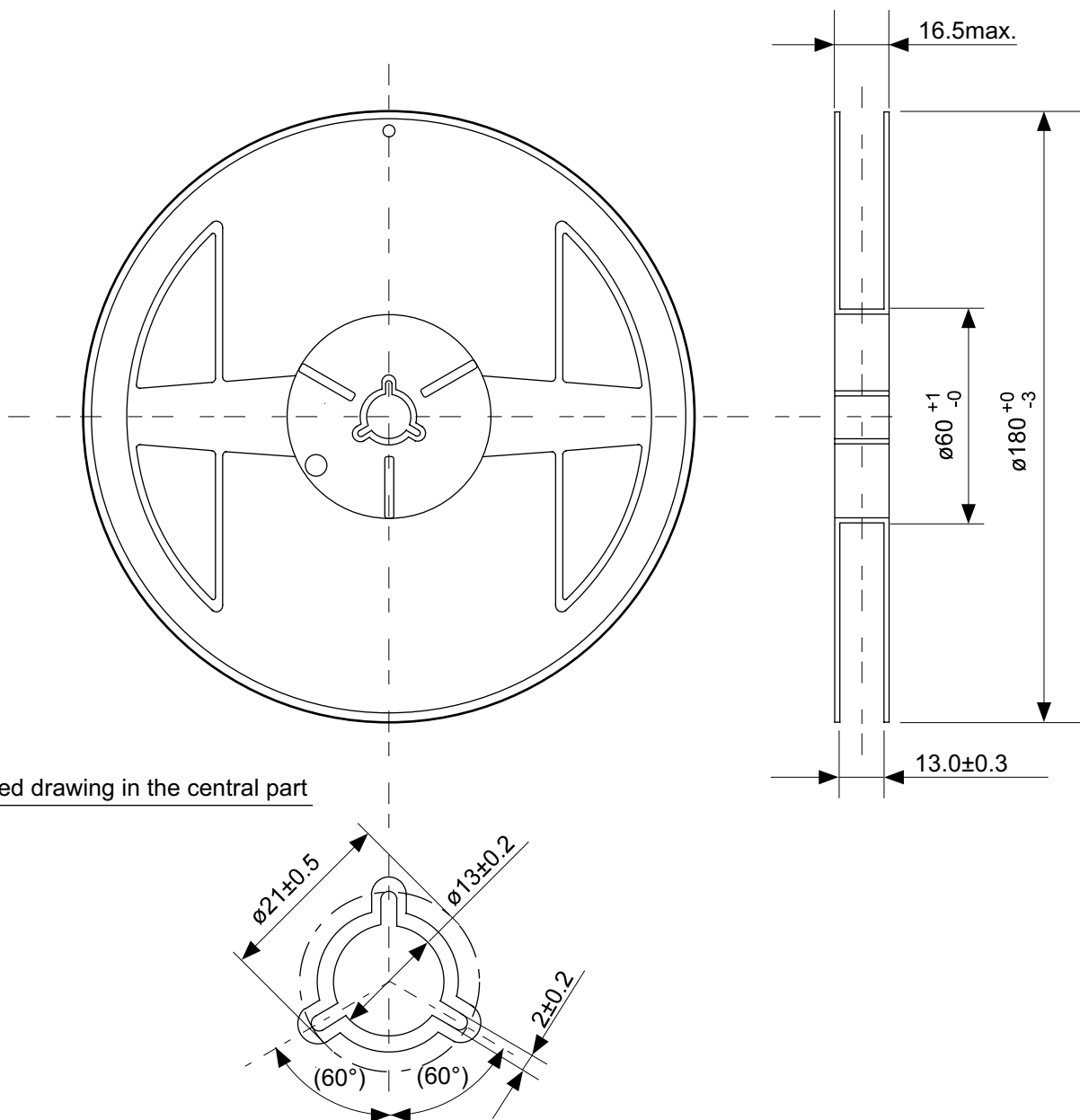
No. UP003-A-P-SD-1.1

|                        |                         |
|------------------------|-------------------------|
| TITLE                  | SOT893-A-PKG Dimensions |
| No.                    | UP003-A-P-SD-1.1        |
| SCALE                  |                         |
| UNIT                   | mm                      |
|                        |                         |
| Seiko Instruments Inc. |                         |



No. UP003-A-C-SD-1.1

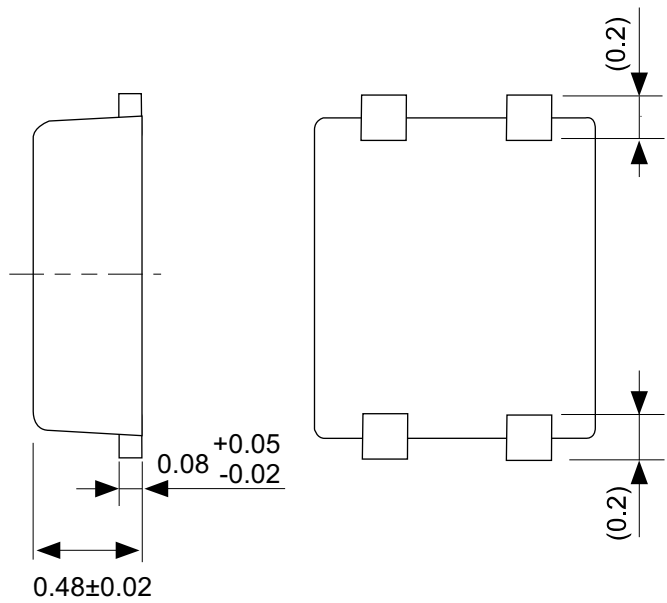
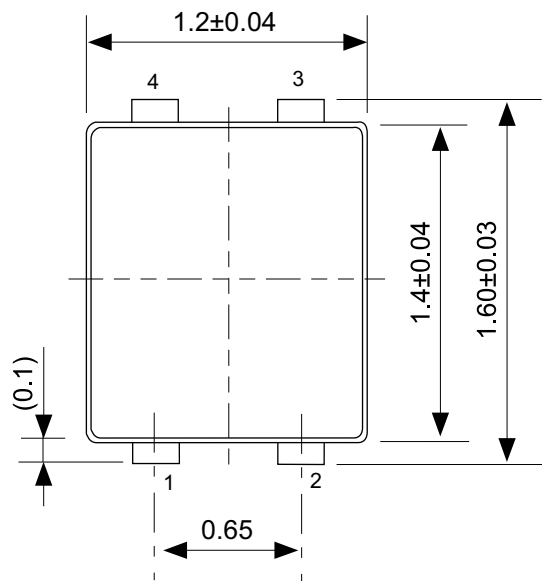
|                        |                       |
|------------------------|-----------------------|
| TITLE                  | SOT893-A-Carrier Tape |
| No.                    | UP003-A-C-SD-1.1      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |



Enlarged drawing in the central part

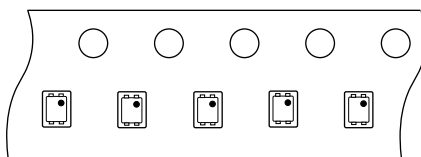
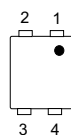
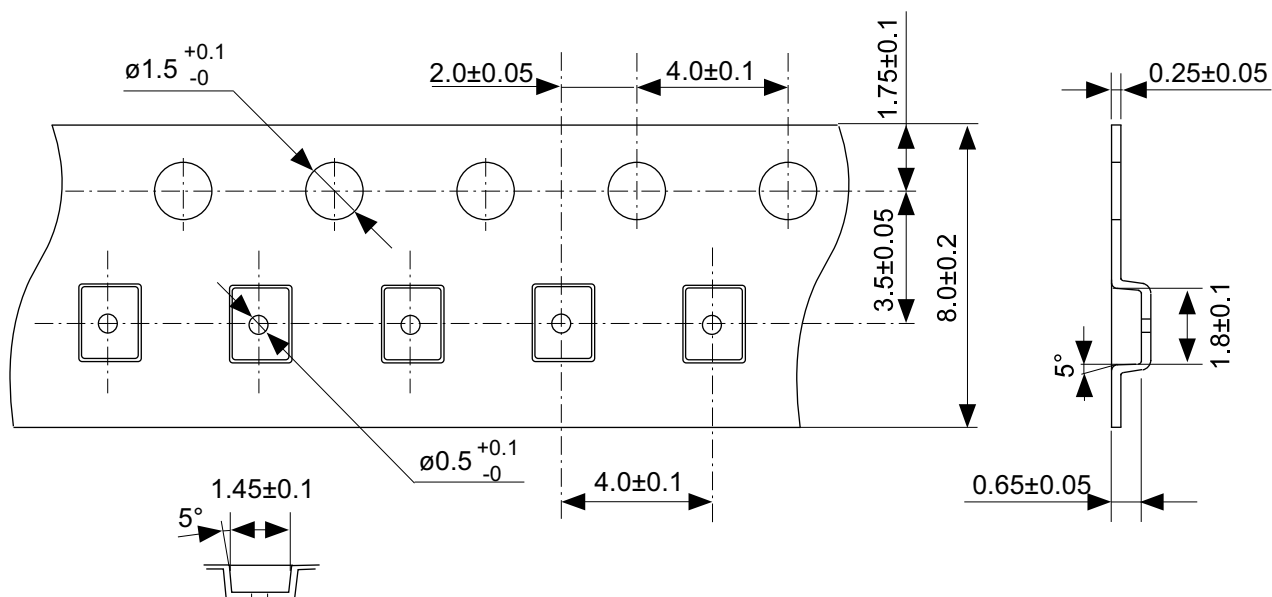
No. UP003-A-R-SD-1.1

|                        |                  |      |       |
|------------------------|------------------|------|-------|
| TITLE                  | SOT893-A-Reel    |      |       |
| No.                    | UP003-A-R-SD-1.1 |      |       |
| SCALE                  |                  | QTY. | 1,000 |
| UNIT                   | mm               |      |       |
|                        |                  |      |       |
| Seiko Instruments Inc. |                  |      |       |



No. PF004-A-P-SD-4.0

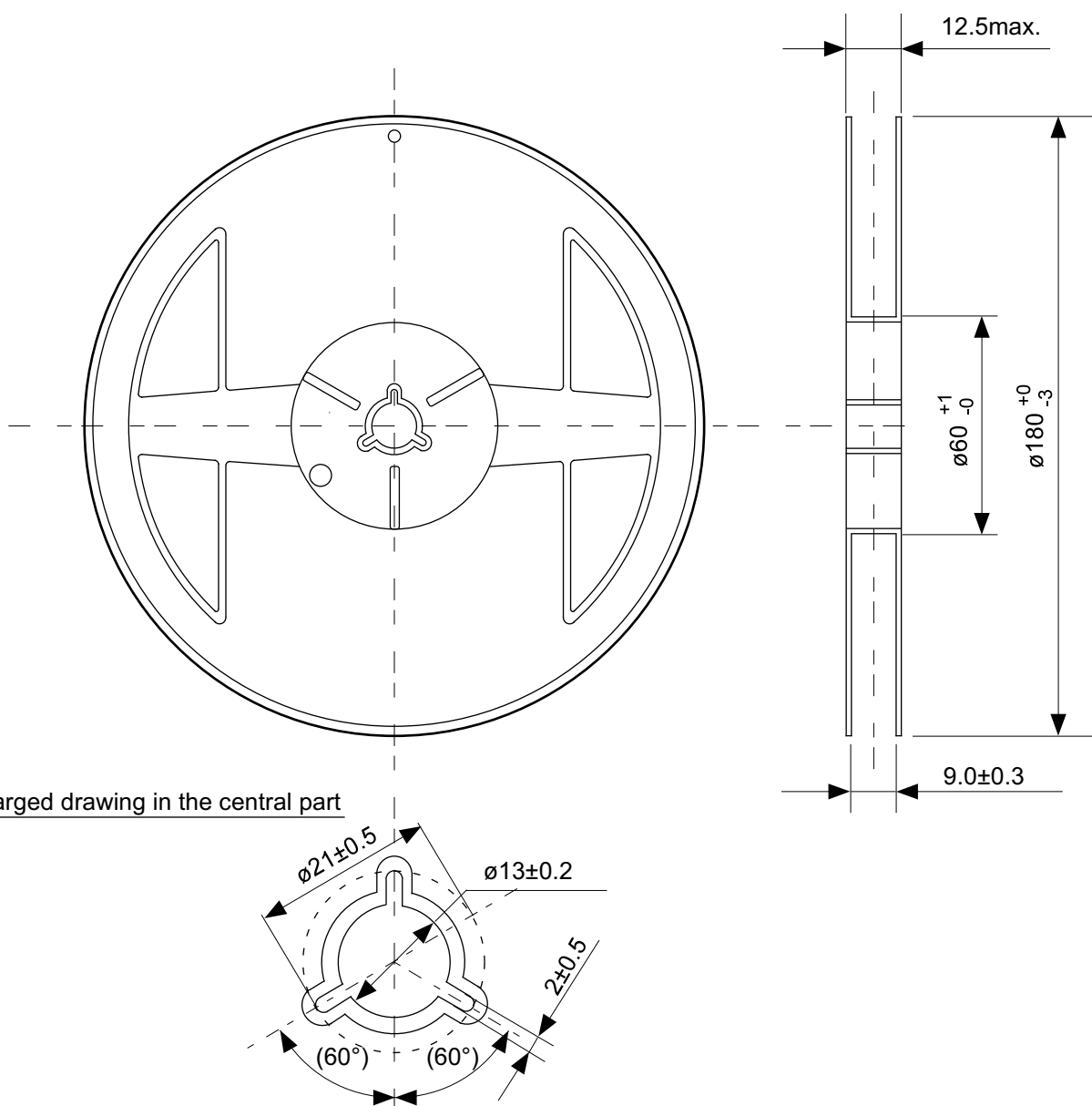
|                        |                         |
|------------------------|-------------------------|
| TITLE                  | SNT-4A-A-PKG Dimensions |
| No.                    | PF004-A-P-SD-4.0        |
| SCALE                  |                         |
| UNIT                   | mm                      |
|                        |                         |
| Seiko Instruments Inc. |                         |



Feed direction

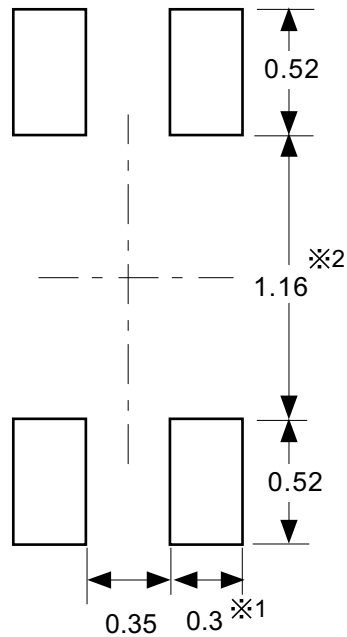
No. PF004-A-C-SD-1.0

|                        |                       |
|------------------------|-----------------------|
| TITLE                  | SNT-4A-A-Carrier Tape |
| No.                    | PF004-A-C-SD-1.0      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |



No. PF004-A-R-SD-1.0

|                        |                  |      |       |
|------------------------|------------------|------|-------|
| TITLE                  | SNT-4A-A-Reel    |      |       |
| No.                    | PF004-A-R-SD-1.0 |      |       |
| SCALE                  |                  | QTY. | 5,000 |
| UNIT                   | mm               |      |       |
|                        |                  |      |       |
| Seiko Instruments Inc. |                  |      |       |



※1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.).

※2. パッケージ中央にランドパターンを広げないでください (1.10 mm ~ 1.20 mm)。

- 注意
1. パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。
  2. パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から0.03 mm以下にしてください。
  3. マスク開口サイズと開口位置はランドパターンと合わせてください。
  4. 詳細は "SNTパッケージ活用の手引き" を参照してください。

※1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).

※2. Do not widen the land pattern to the center of the package (1.10 mm to 1.20 mm).

- Caution**
1. Do not do silkscreen printing and solder printing under the mold resin of the package.
  2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
  3. Match the mask aperture size and aperture position with the land pattern.
  4. Refer to "SNT Package User's Guide" for details.

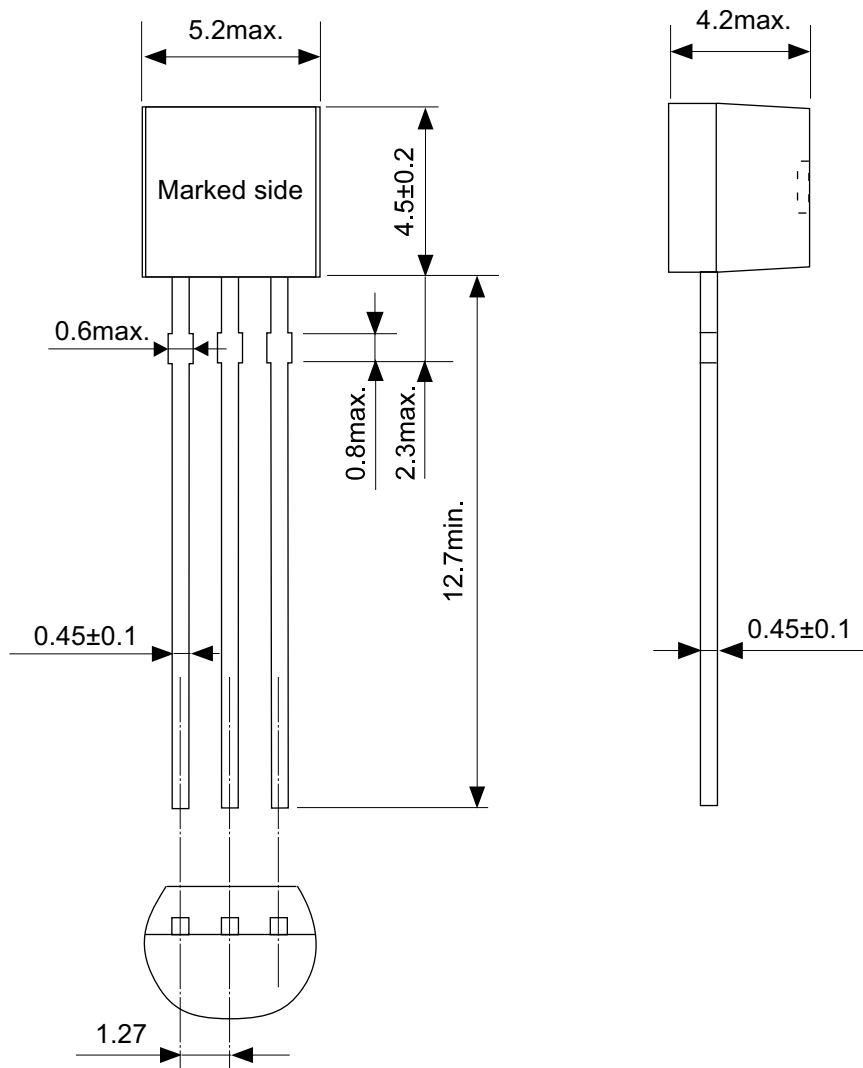
※1. 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.).

※2. 请勿向封装中间扩展焊盘模式 (1.10 mm ~ 1.20 mm)。

- 注意
1. 请勿在树脂型封装的下面印刷丝网、焊锡。
  2. 在封装下、布线上的阻焊膜厚度 (从焊盘模式表面起) 请控制在0.03 mm以下。
  3. 掩膜的开口尺寸和开口位置请与焊盘模式对齐。
  4. 详细内容请参阅 "SNT封装的应用指南"。

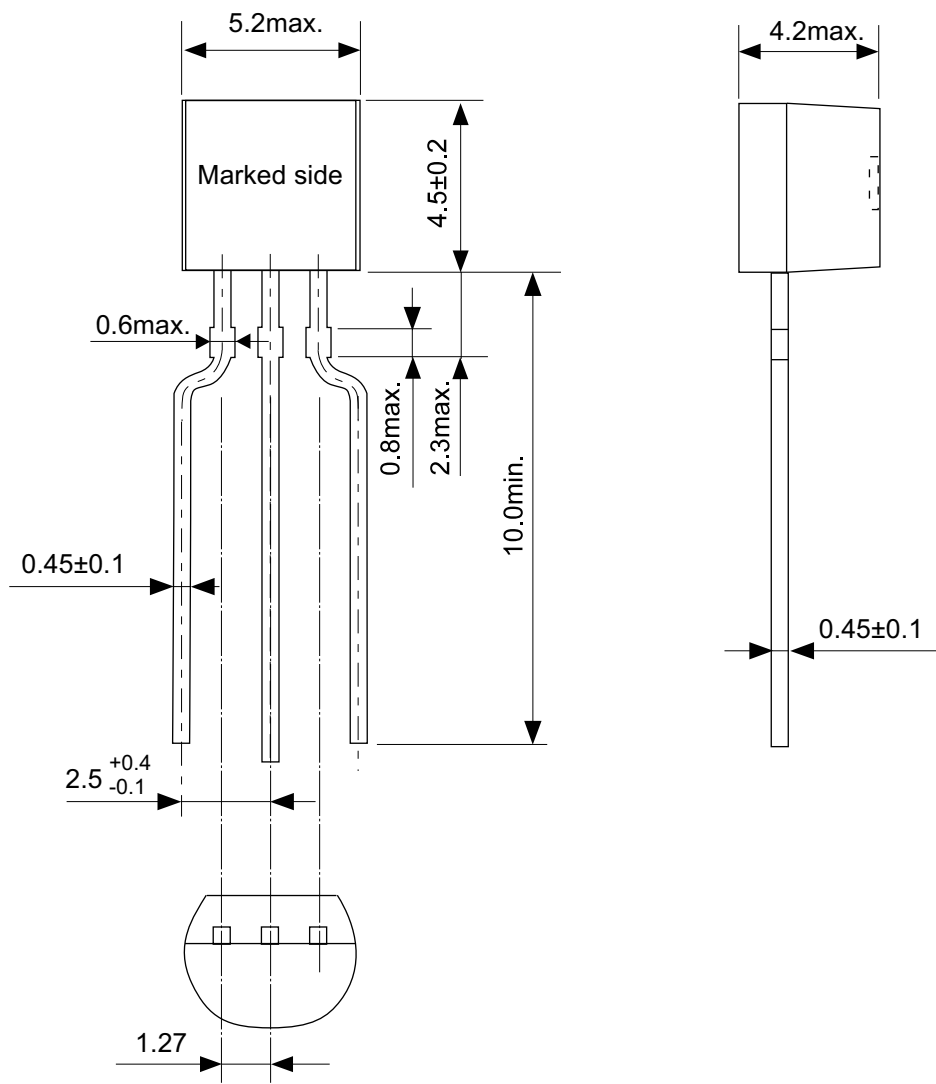
No. PF004-A-L-SD-4.0

|                        |                              |
|------------------------|------------------------------|
| TITLE                  | SNT-4A-A-Land Recommendation |
| No.                    | PF004-A-L-SD-4.0             |
| SCALE                  |                              |
| UNIT                   | mm                           |
|                        |                              |
| Seiko Instruments Inc. |                              |



No. YS003-D-P-SD-2.0

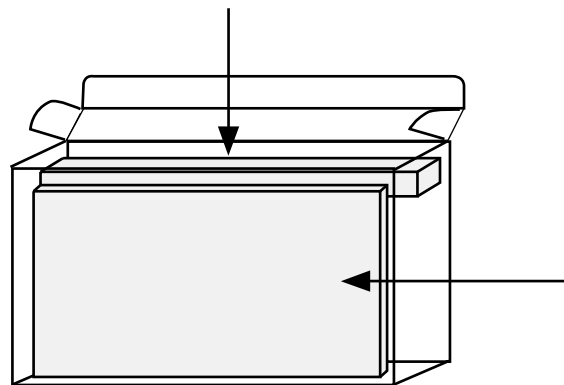
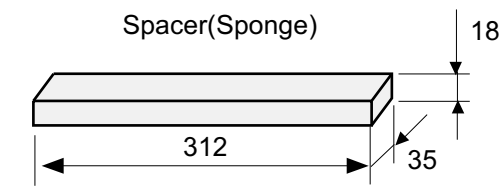
|                        |                       |
|------------------------|-----------------------|
| TITLE                  | TO92-D-PKG Dimensions |
| No.                    | YS003-D-P-SD-2.0      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |



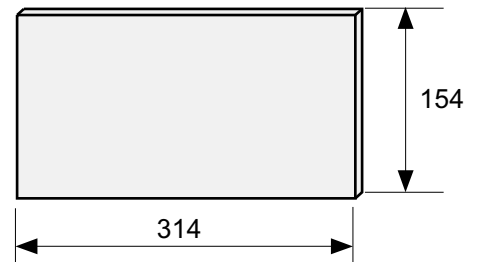
No. YZ003-E-P-SD-2.0

|                        |                       |
|------------------------|-----------------------|
| TITLE                  | TO92-E-PKG Dimensions |
| No.                    | YZ003-E-P-SD-2.0      |
| SCALE                  |                       |
| UNIT                   | mm                    |
|                        |                       |
| Seiko Instruments Inc. |                       |

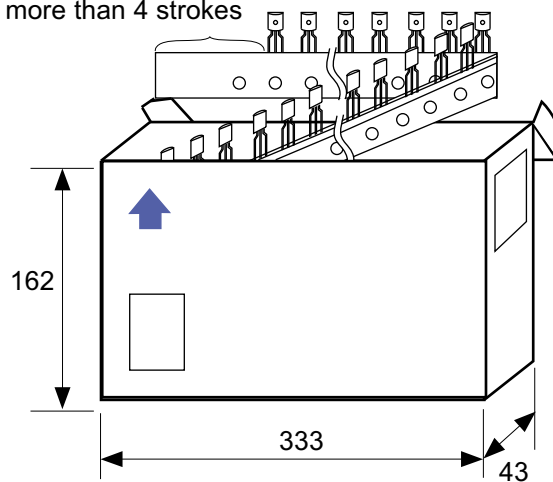
|                        |                    |
|------------------------|--------------------|
| TITLE                  | TO92-E-Radial Tape |
| No.                    | YZ003-E-C-SD-1.1   |
| SCALE                  |                    |
| UNIT                   | mm                 |
|                        |                    |
| Seiko Instruments Inc. |                    |



Side spacer placed in front side



Space more than 4 strokes



No. YZ003-E-Z-SD-2.0

|                        |                     |      |       |
|------------------------|---------------------|------|-------|
| TITLE                  | TO92-E-Ammo Packing |      |       |
| No.                    | YZ003-E-Z-SD-2.0    |      |       |
| SCALE                  |                     | QTY. | 2,000 |
| UNIT                   | mm                  |      |       |
|                        |                     |      |       |
| Seiko Instruments Inc. |                     |      |       |



Seiko Instruments Inc.  
[www.sii-ic.com](http://www.sii-ic.com)

- The information described herein is subject to change without notice.
- Seiko Instruments Inc. is not responsible for any problems caused by circuits or diagrams described herein whose related industrial properties, patents, or other rights belong to third parties. The application circuit examples explain typical applications of the products, and do not guarantee the success of any specific mass-production design.
- When the products described herein are regulated products subject to the Wassenaar Arrangement or other agreements, they may not be exported without authorization from the appropriate governmental authority.
- Use of the information described herein for other purposes and/or reproduction or copying without the express permission of Seiko Instruments Inc. is strictly prohibited.
- The products described herein cannot be used as part of any device or equipment affecting the human body, such as exercise equipment, medical equipment, security systems, gas equipment, vehicle equipment, in-vehicle equipment, aviation equipment, aerospace equipment, and nuclear-related equipment, without prior written permission of Seiko Instruments Inc.
- The products described herein are not designed to be radiation-proof.
- Although Seiko Instruments Inc. exerts the greatest possible effort to ensure high quality and reliability, the failure or malfunction of semiconductor products may occur. The user of these products should therefore give thorough consideration to safety design, including redundancy, fire-prevention measures, and malfunction prevention, to prevent any accidents, fires, or community damage that may ensue.

## Данный компонент на территории Российской Федерации

**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9